TEXAS INSTRUMENTS

AFE539F1-Q1 Automotive, 10-Bit Smart Analog Front End for Constant Power Discharge With PWM Output

1 Features

- AEC-Q100 qualified for automotive applications:
  - Temperature grade 1: –40°C to +125°C, T_A
- Constant power-dissipation control state-machine
  - 10-bit analog-to-digital converter (ADC) input
  - 7-bit duty-cycle pulse-width modulation (PWM) output
  - Standalone operation from nonvolatile memory (NVM)
- Automatically detects I²C or SPI
  - 1.62-V V_{IH} with V_{DD} = 5.5 V
- VREF/MODE pin selects between programming and standalone modes
- User-programmable NVM
- Internal, external, or VDD reference
- Wide operating range
  - Power supply: 1.8 V to 5.5 V
- Tiny package: 16-pin WQFN (3 mm × 3 mm)

2 Applications

- Automotive DC-link capacitor discharge circuit
- Elevator main control panel

3 Description

The AFE539F1-Q1 is a 10-bit smart analog front end (AFE) targeted for constant power-dissipation control. The AFE539F1-Q1 can be used everywhere where constant power dissipation is desired on a resistive load independently on applied voltage. The AFE539F1-Q1 has an ADC input and a PWM output. This device has an integrated state machine that is preprogrammed as a constant power-dissipation controller. The AFE539F1-Q1 is an excellent choice for automotive DC-link capacitor discharge circuit and general constant-power-heating applications. The AFE539F1-Q1 works independently from parameters programmed into the NVM, which enable this smart AFE for *processor-less* applications and design reuse. This device also automatically detects I²C or SPI, and has an internal reference.

Package Information

PART NUMBER	PACKAGE[1]	PACKAGE SIZE[2]
AFE539F1-Q1	RTE (WQFN, 16)	3 mm x 3 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

(2) The package size (length × width) is a nominal value and includes pins, where applicable.
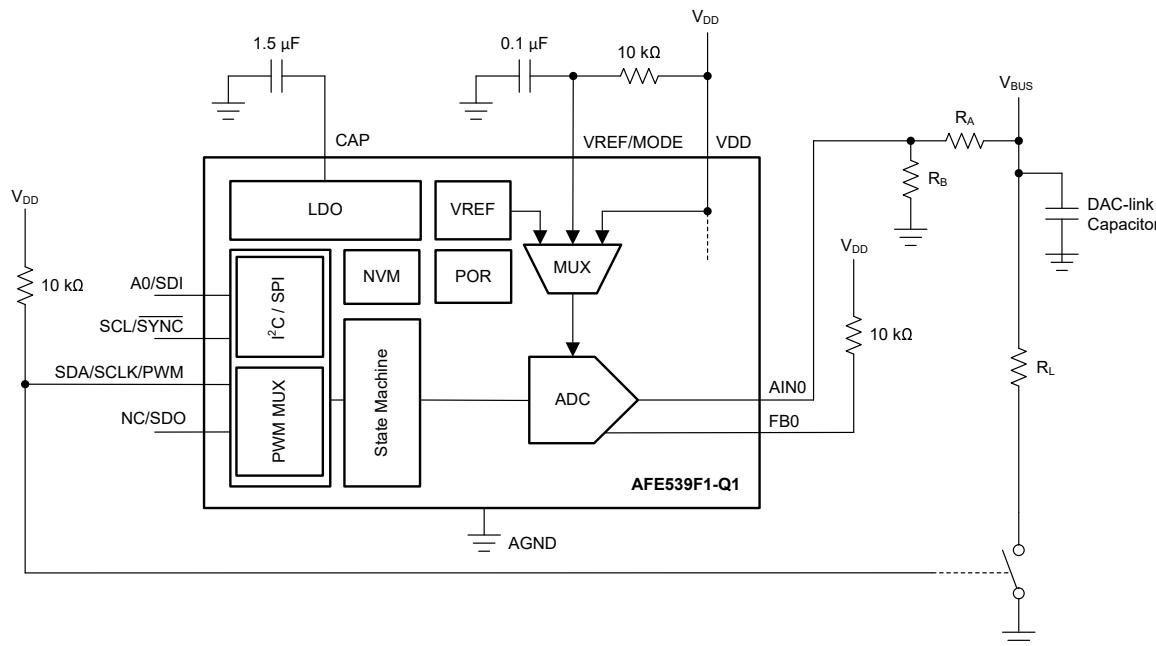
Constant Power Discharge Circuit Using AFE539F1-Q1

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4 Revision History

DATE	REVISION	NOTES
July 2023	*	Initial release

5 Pin Configuration and Functions
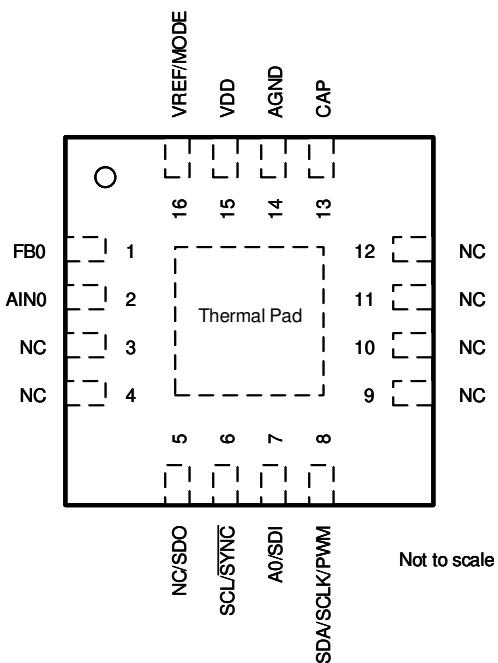
Figure 5-1. RTE Package, 16-pin WQFN (Top View)

Table 5-1. Pin Functions

PIN NO.	NAME	TYPE	DESCRIPTION
1	FB0	Input	Connect this pin to VDD with a pullup resistor.
2	AIN0	Input	Analog input for ADC0.
3	NC	—	Not connected.
4	NC	—	Not connected.
5	NC/SDO	Input/Output	This pin is configurable as SDO. For SDO function, connect this pin to the IO voltage with an external pullup resistor. Leave this pin unconnected if not configured as SDO.
6	SCL/$\overline{\text{SYNC}}$	Output	I^2C serial interface clock or SPI chip select input. Connect this pin to the IO voltage using an external pullup resistor.
7	A0/SDI	Input	Address configuration input for I^2C or serial data input for SPI. In A0 function, connect this pin to VDD, AGND, SDA, or SCL for address configuration. In SDI function, this pin does not need to be pulled up or pulled down.
8	SDA/SCLK/PWM	Input/Output	Bidirectional I^2C serial data bus or SPI clock input. Connect this pin to the IO voltage using an external pullup resistor. This pin acts as the PWM output for constant power-dissipation control. Pull the VREF/MODE pin high to enable PWM output.
9	NC	—	Not connected.
10	NC	—	Not connected.
11	NC	—	Not connected.
12	NC	—	Not connected.
13	CAP	Power	External bypass capacitor for the internal LDO. Connect a capacitor (approximately 1.5 µF) between CAP and AGND.
14	AGND	Ground	Ground reference point for all circuitry on the device.
15	VDD	Power	Supply voltage: 1.8 V to 5.5 V

Table 5-1. Pin Functions (continued)

PIN		TYPE	DESCRIPTION
NO.	NAME		
16	VREF/ MODE	Input	External reference or interface mode select input. Connect a capacitor (approximately 0.1 μF) between VREF/MODE and AGND. Use a pullup resistor to VDD when the external reference is not used. Make sure that this pin does not ramp up before VDD. In case an external reference is used or when in interface select mode, make sure the reference ramps up after VDD. In interface select mode. Pull this pin low to enable I^{2}C/SPI communication. Pull this pin high to enable PWM output.
Thermal pad	Thermal Pad	Ground	Connect the thermal pad to AGND.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
V_{DD}	Supply voltage, V_{DD} to AGND	−0.3	6	V
	Digital inputs to AGND	−0.3	V_{DD} + 0.3	V
	V_{FBX} to AGND	−0.3	V_{DD} + 0.3	V
	A_{IN0} to AGND	−0.3	V_{DD} + 0.3	V
V_{REF}	External reference, V_{REF} to AGND	−0.3	V_{DD} + 0.3	V
	Current into any pin except the AIN0, VDD, and AGND pins	−10	10	mA
T_J	Junction temperature	−40	150	°C
T_{stg}	Storage temperature	−65	150	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

6.2 ESD Ratings

				VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002[1] HBM ESD classification level 2		±2000	V
		Charged device model (CDM), per AEC Q100-011 CDM ESD classification level C4B	Corner pins (1, 4, 5, 8, 9, 12, 13, and 16)	±750	
			All pins	±500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{DD}	Positive supply voltage to ground (AGND)	1.7		5.5	V
V_{REF}	External reference to ground (AGND)	1.7		V_{DD}	V
V_{IH}	Digital input high voltage, 1.7 V < V_{DD} ≤ 5.5 V	1.62			V
V_{IL}	Digital input low voltage			0.4	V
C_{CAP}	External capacitor on CAP pin	0.5		15	µF
T_A	Ambient temperature	−40		125	°C

6.4 Thermal Information

	THERMAL METRIC[1]	AFE539F1-Q1 RTE (WQFN) 16 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	49	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	50	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	24.1	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	1.1	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	24.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	8.7	°C/W

(1) For information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics application report*.

6.5 Electrical Characteristics: ADC Input

minimum and maximum specifications at –40°C ≤ T_A ≤ +125°C and typical specifications at T_A = 25°C, 1.7 V ≤ V_{DD} ≤ 5.5 V, reference input tied to VDD, gain = 1 ×, and digital inputs at VDD or AGND (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC PERFORMANCE						
	Resolution		10			Bits
INL	Integral nonlinearity[1] [2]		–2		2	LSB
DNL	Differential nonlinearity[1] [2]		–1		1	LSB
	Offset error[1] [2]	1.7 V ≤ V_{DD} < 2.7 V	–5	0	5	mV
		2.7 V ≤ V_{DD} ≤ 5.5 V	–5	0	5	
	Gain error[1] [2]		–1		1	%FSR
INPUT						
	Input voltage range	External V_{REF} = V_{DD}	0		V_{DD}	V
DYNAMIC PERFORMANCE						
	Data rate[2]	ADC averaging setting is 4 samples	1406		2008	SPS
	Sampling capacitor			10		pF

(1) For external reference and internal reference V_{DD} ≥ 1.21 x gain + 0.2 V, between end-point codes: 8d to 1016d.
(2) Specified by design and characterization, not production tested.

Product Folder Links: *AFE539F1-Q1*

6.6 Electrical Characteristics: General

minimum and maximum specifications at $-40°C \leq T_A \leq +125°C$ and typical specifications at $T_A = 25°C$, $1.7\ V \leq V_{DD} \leq 5.5\ V$, reference input tied to VDD, gain = 1 × and digital inputs at VDD or AGND (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INTERNAL REFERENCE						
	Initial accuracy	$T_A = 25°C$ for all measurements	1.1979	1.212	1.224	V
	Reference output temperature coefficient[1] [2]				60	ppm/°C
EXTERNAL REFERENCE						
	External reference input range		1.7		V_{DD}	V
	V_{REF} input impedance[1]			192		kΩ
EEPROM						
	Endurance[1]	$-40°C \leq T_A \leq +85°C$		20000		Cycles
		$T_A = 125°C$		1000		
	Data retention[1]			50		Years
	EEPROM programming write cycle time[1]				200	ms
	Device boot-up time[1]	Time taken from power valid ($V_{DD} \geq 1.7\ V$) to output valid state (output state as programmed in EEPROM), 0.5-µF capacitor on the CAP pin		5		ms
DIGITAL INPUTS						
	Pin capacitance	Per pin		10		pF
POWER						
I_{DD}	Current flowing into VDD	Sleep mode, internal reference powered down, external reference at 5.5 V			28	µA
	Current flowing into VDD[1]	Sleep mode, internal reference enabled, additional current through internal reference		10		
		ADC channel enabled, internal reference enabled, additional current through internal reference		12.5		µA-ch
		Normal operation, state-machine enabled		900		µA

(1) Specified by design and characterization, not production tested.
(2) Measured at –40°C and +125°C and calculated the slope.

6.7 Timing Requirements: I²C Standard Mode

all input signals are timed from VIL to 70% of $V_{pull-up}$, 1.7 V ≤ V_{DD} ≤ 5.5 V, −40°C ≤ T_A ≤ +125°C, and 1.7 V ≤ $V_{pull-up}$ ≤ V_{DD}

		MIN	NOM	MAX	UNIT
f_{SCLK}	SCL frequency			100	kHz
t_{BUF}	Bus free time between stop and start conditions	4.7			µs
t_{HDSTA}	Hold time after repeated start	4			µs
t_{SUSTA}	Repeated start setup time	4.7			µs
t_{SUSTO}	Stop condition setup time	4			µs
t_{HDDAT}	Data hold time	0			ns
t_{SUDAT}	Data setup time	250			ns
t_{LOW}	SCL clock low period	4700			ns
t_{HIGH}	SCL clock high period	4000			ns
t_F	Clock and data fall time			300	ns
t_R	Clock and data rise time			1000	ns
t_{VDDAT}	Data valid time, R = 360 Ω, C_{trace} = 23 pF, C_{probe} = 10 pF			3.45	µs
t_{VDACK}	Data valid acknowledge time, R = 360 Ω, C_{trace} = 23 pF, C_{probe} = 10 pF			3.45	µs

6.8 Timing Requirements: I²C Fast Mode

all input signals are timed from VIL to 70% of $V_{pull-up}$, 1.7 V ≤ V_{DD} ≤ 5.5 V, −40°C ≤ T_A ≤ +125°C, and 1.7 V ≤ $V_{pull-up}$ ≤ V_{DD}

		MIN	NOM	MAX	UNIT
f_{SCLK}	SCL frequency			400	kHz
t_{BUF}	Bus free time between stop and start conditions	1.3			µs
t_{HDSTA}	Hold time after repeated start	0.6			µs
t_{SUSTA}	Repeated start setup time	0.6			µs
t_{SUSTO}	Stop condition setup time	0.6			µs
t_{HDDAT}	Data hold time	0			ns
t_{SUDAT}	Data setup time	100			ns
t_{LOW}	SCL clock low period	1300			ns
t_{HIGH}	SCL clock high period	600			ns
t_F	Clock and data fall time			300	ns
t_R	Clock and data rise time			300	ns
t_{VDDAT}	Data valid time, R = 360 Ω, C_{trace} = 23 pF, C_{probe} = 10 pF			0.9	µs
t_{VDACK}	Data valid acknowledge time, R = 360 Ω, C_{trace} = 23 pF, C_{probe} = 10 pF			0.9	µs

6.9 Timing Requirements: I²C Fast Mode Plus

all input signals are timed from VIL to 70% of $V_{pull-up}$, 1.7 V ≤ V_{DD} ≤ 5.5 V, −40°C ≤ T_A ≤ +125°C, and 1.7 V ≤ $V_{pull-up}$ ≤ V_{DD}

		MIN	NOM	MAX	UNIT
f_{SCLK}	SCL frequency			1	MHz
t_{BUF}	Bus free time between stop and start conditions	0.5			µs
t_{HDSTA}	Hold time after repeated start	0.26			µs
t_{SUSTA}	Repeated start setup time	0.26			µs
t_{SUSTO}	Stop condition setup time	0.26			µs
t_{HDDAT}	Data hold time	0			ns
t_{SUDAT}	Data setup time	50			ns
t_{LOW}	SCL clock low period	0.5			µs
t_{HIGH}	SCL clock high period	0.26			µs
t_F	Clock and data fall time			120	ns
t_R	Clock and data rise time			120	ns
t_{VDDAT}	Data valid time, R = 360 Ω, C_{trace} = 23 pF, C_{probe} = 10 pF			0.45	µs
t_{VDACK}	Data valid acknowledge time, R = 360 Ω, C_{trace} = 23 pF, C_{probe} = 10 pF			0.45	µs

Product Folder Links: *AFE539F1-Q1*

6.10 Timing Requirements: SPI Write Operation

all input signals are specified with $t_r = t_f$ = 1 V/ns (10% to 90% of V_{IO}) and timed from a voltage level of (VIL + VIH) / 2, 1.7 V ≤ V_{IO} ≤ 5.5 V, 1.7 V ≤ V_{DD} ≤ 5.5 V, and −40°C ≤ T_A ≤ +125°C

		MIN	NOM	MAX	UNIT
f_{SCLK}	Serial clock frequency			50	MHz
$t_{SCLKHIGH}$	SCLK high time	9			ns
$t_{SCLKLOW}$	SCLK low time	9			ns
t_{SDIS}	SDI setup time	8			ns
t_{SDIH}	SDI hold time	8			ns
t_{CSS}	$\overline{SYNC}$ to SCLK falling edge setup time	18			ns
t_{CSH}	SCLK falling edge to $\overline{SYNC}$ rising edge	10			ns
t_{CSHIGH}	$\overline{SYNC}$ high time	50			ns
$t_{DACWAIT}$	Sequential update wait time (time between subsequent $\overline{SYNC}$ rising edges) for same channel	2			μs

6.11 Timing Requirements: SPI Read and Daisy Chain Operation (FSDO = 0)

all input signals are specified with $t_r = t_f$ = 1 V/ns (10% to 90% of V_{IO}) and timed from a voltage level of (VIL + VIH) / 2, 1.7 V ≤ V_{IO} ≤ 5.5 V, 1.7 V ≤ V_{DD} ≤ 5.5 V, −40°C ≤ T_A ≤ +125°C, and FSDO = 0

		MIN	NOM	MAX	UNIT
f_{SCLK}	Serial clock frequency			1.25	MHz
$t_{SCLKHIGH}$	SCLK high time	350			ns
$t_{SCLKLOW}$	SCLK low time	350			ns
t_{SDIS}	SDI setup time	8			ns
t_{SDIH}	SDI hold time	8			ns
t_{CSS}	$\overline{SYNC}$ to SCLK falling edge setup time	400			ns
t_{CSH}	SCLK falling edge to $\overline{SYNC}$ rising edge	400			ns
t_{CSHIGH}	$\overline{SYNC}$ high time	1			μs
t_{SDODLY}	SCLK rising edge to SDO falling edge, I_{OL} ≤ 5 mA, C_L = 20 pF			300	ns

6.12 Timing Requirements: SPI Read and Daisy Chain Operation (FSDO = 1)

all input signals are specified with $t_r = t_f$ = 1 V/ns (10% to 90% of V_{IO}) and timed from a voltage level of (VIL + VIH) / 2, 1.7 V ≤ V_{IO} ≤ 5.5 V, 1.7 V ≤ V_{DD} ≤ 5.5 V, −40°C ≤ T_A ≤ +125°C, and FSDO = 1

		MIN	NOM	MAX	UNIT
f_{SCLK}	Serial clock frequency			2.5	MHz
$t_{SCLKHIGH}$	SCLK high time	175			ns
$t_{SCLKLOW}$	SCLK low time	175			ns
t_{SDIS}	SDI setup time	8			ns
t_{SDIH}	SDI hold time	8			ns
t_{CSS}	$\overline{SYNC}$ to SCLK falling edge setup time	300			ns
t_{CSH}	SCLK falling edge to $\overline{SYNC}$ rising edge	300			ns
t_{CSHIGH}	$\overline{SYNC}$ high time	1			μs
t_{SDODLY}	SCLK rising edge to SDO falling edge, I_{OL} ≤ 5 mA, C_L = 20 pF			300	ns

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Product Folder Links: AFE539F1-Q1

6.13 Timing Requirements: PWM Output

all input signals are timed from VIL to 70% of $V_{pull-up}$, 1.7 V ≤ V_{DD} ≤ 5.5, −40°C ≤ T_A ≤ +125°C, and 1.7 V ≤ $V_{pull-up}$ ≤ V_{DD}

		MIN	NOM	MAX	UNIT
f_{PWMOUT}	PWM frequency[1]	0.218		48.828	kHz
t_{PWMOHI}	PWM high time	1			µs
t_{PWMOLO}	PWM low time	1			µs
$t_{PWMODTY}$	PWM duty cycle	0		100	%

(1)   The frequency range does not account for the internal oscillator frequency error.

6.14 Timing Diagrams
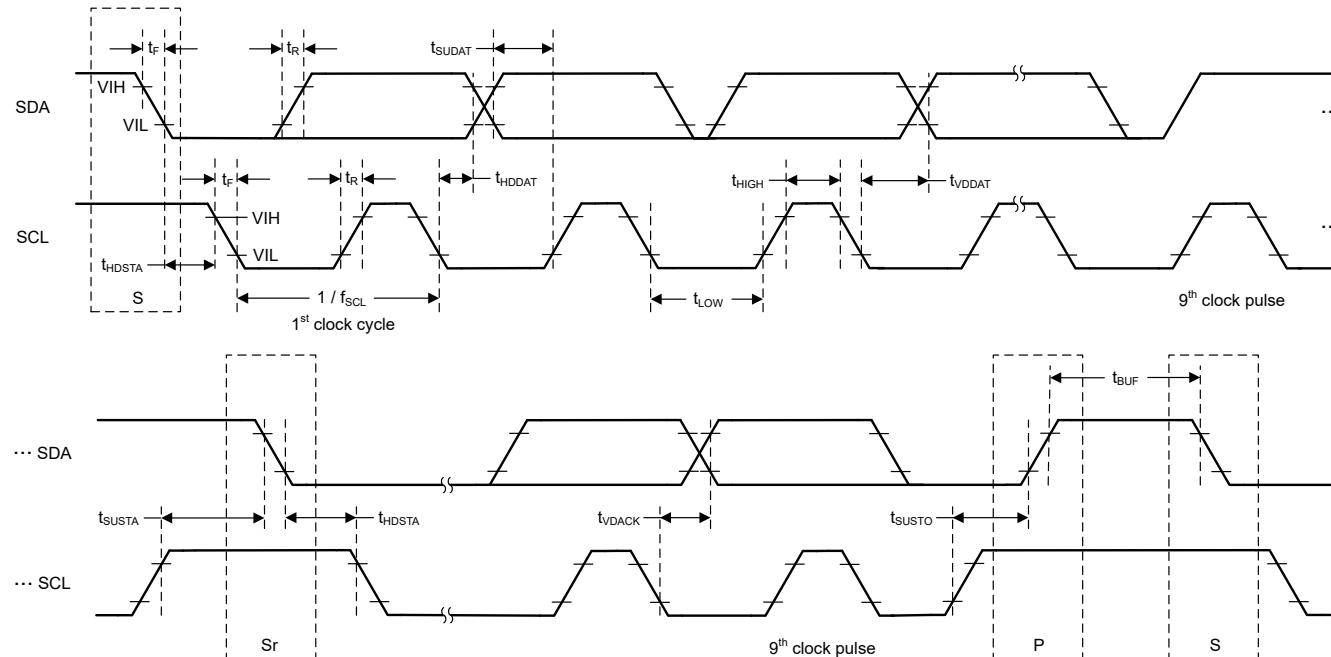
**S**: Start bit, **Sr**: Repeated start bit, **P**: Stop bit

Figure 6-1. I²C Timing Diagram
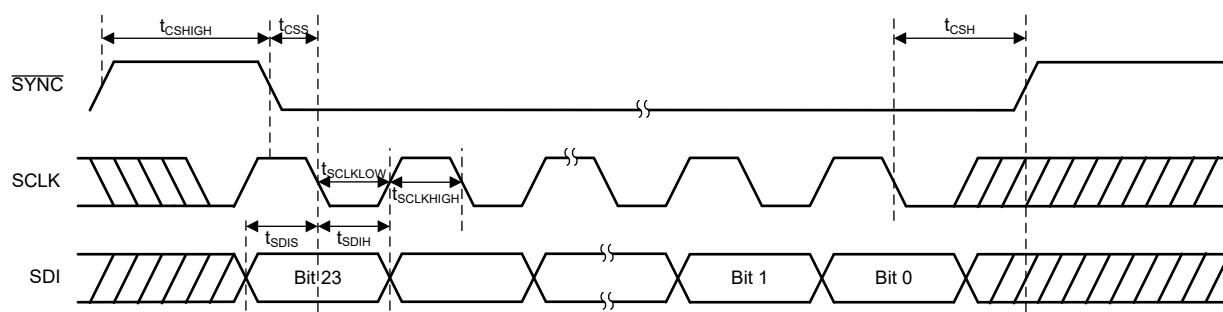
Figure 6-2. SPI Write Timing Diagram
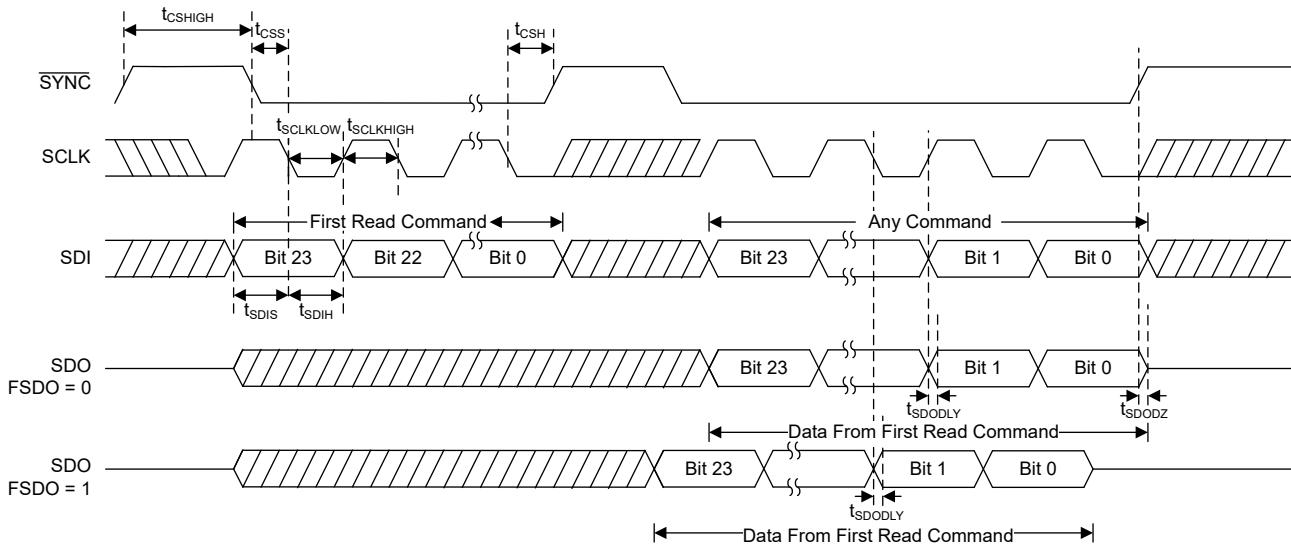
**Figure 6-3. SPI Read Timing Diagram**

6.15 Typical Characteristics

at T_A = 25°C, V_{DD} = 5.5 V, external reference = 5.5 V, and gain = 1 × (unless otherwise noted)
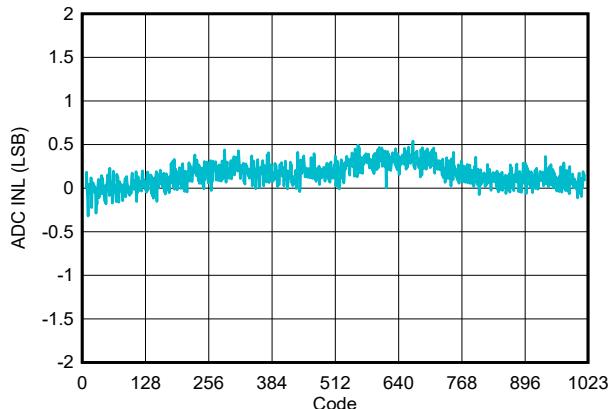

**Figure 6-4. ADC INL vs Digital Output Code**
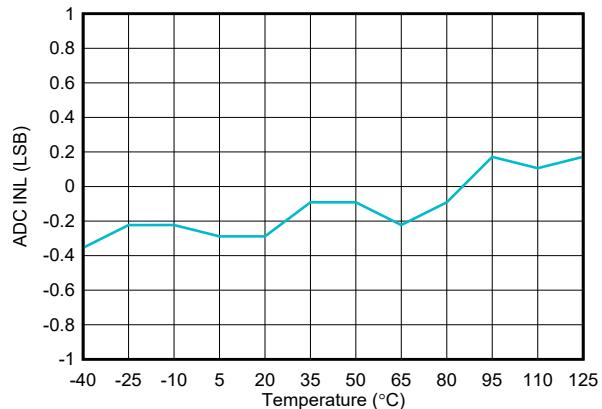
Figure 6-5. ADC INL vs Temperature
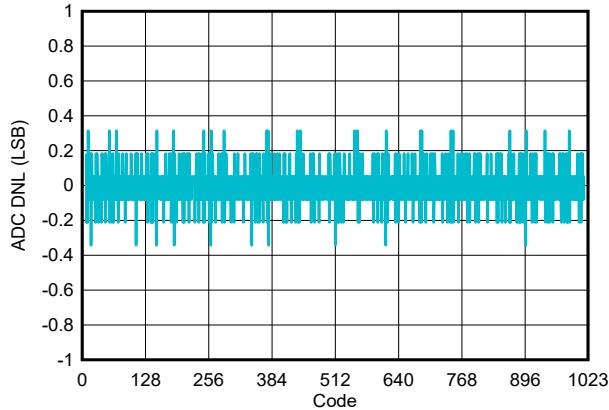
Figure 6-6. ADC DNL vs Digital Output Code
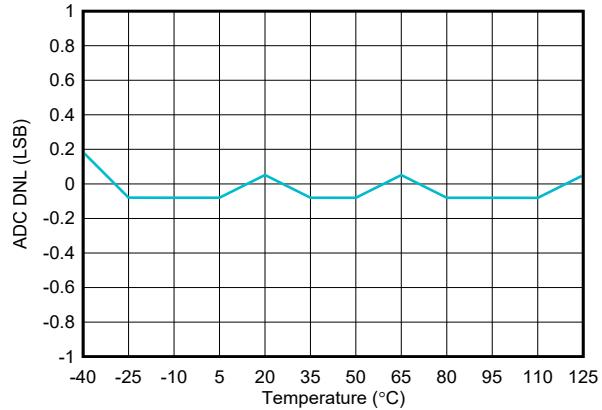
Figure 6-7. ADC DNL vs Temperature
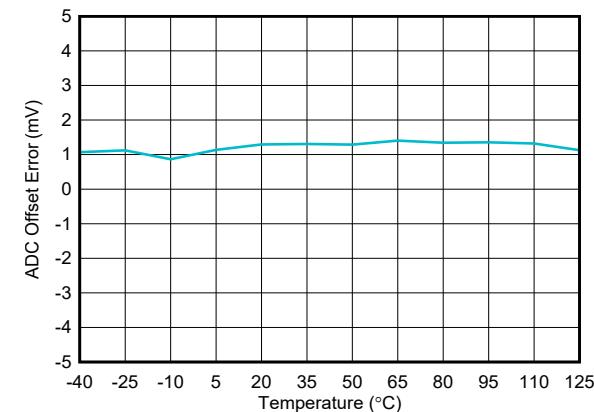
Figure 6-8. ADC Offset Error vs Temperature
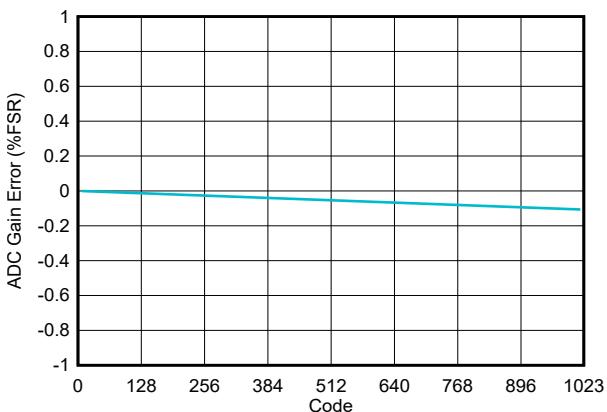
Figure 6-9. ADC Gain Error vs Digital Output Code

Product Folder Links: *AFE539F1-Q1*

6.15 Typical Characteristics (continued)

at T_A = 25°C, V_{DD} = 5.5 V, external reference = 5.5 V, and gain = 1 × (unless otherwise noted)
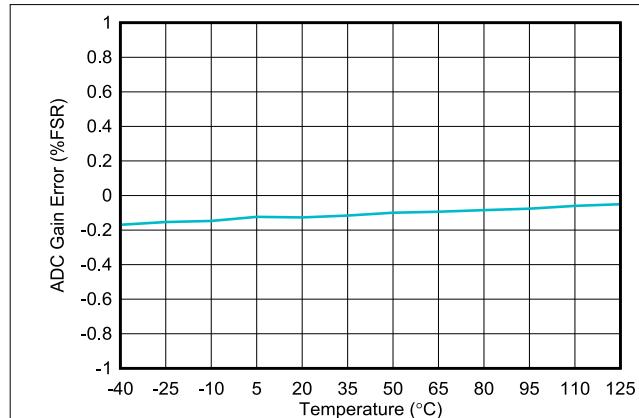
Figure 6-10. ADC Gain Error vs Temperature

Input at mid scale
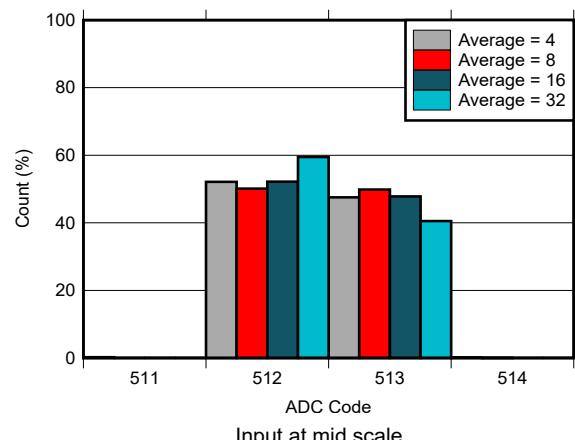
Figure 6-11. ADC Count vs Digital Output Code

Internal reference
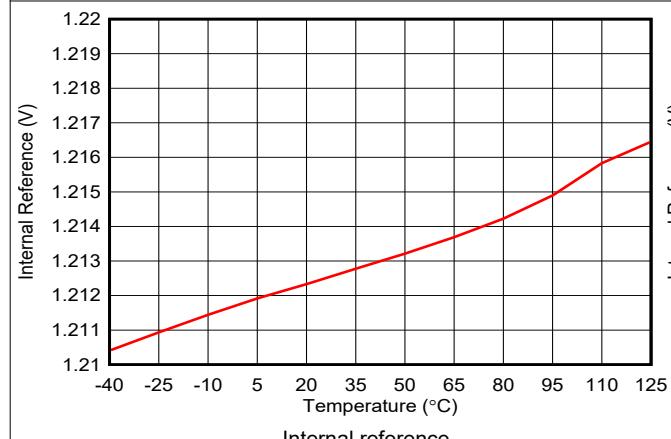
Figure 6-12. Internal Reference vs Temperature

Internal reference
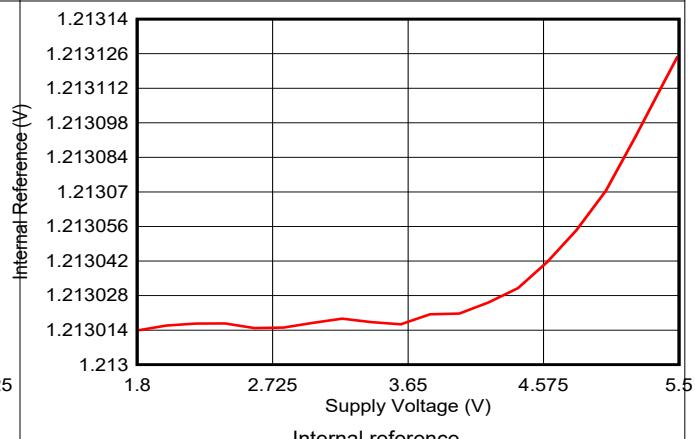
Figure 6-13. Internal Reference vs Supply Voltage
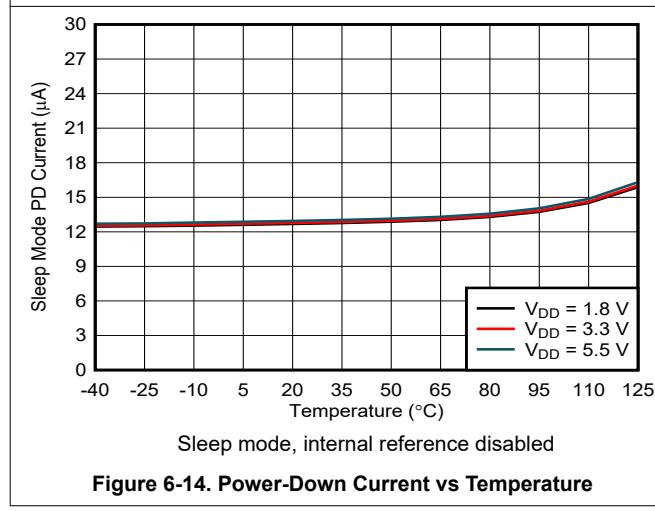
Sleep mode, internal reference disabled

Figure 6-14. Power-Down Current vs Temperature
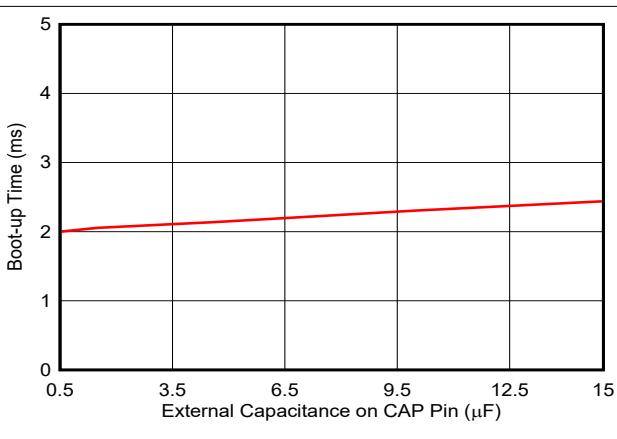
Figure 6-15. Boot-Up Time vs Capacitance on CAP pin

Product Folder Links: AFE539F1-Q1

7 Detailed Description

7.1 Overview

The AFE539F1-Q1 is a 10-bit smart analog front end (AFE) with PWM output and ADC input. The SDA/SCLK pin is re-purposed as the PWM output when the VREF/MODE pin is held high.

The AFE539F1-Q1 provides a preprogrammed state machine that functions as a constant power-dissipation or heating controller. This device contains nonvolatile memory (NVM), an internal reference, automatically detects I^2C and SPI, and a general-purpose input. The device supports Hi-Z power-down modes by default, which can be configured to 10 kΩ-AGND or 100 kΩ-AGND using the NVM. The AFE539F1-Q1 has a power-on-reset (POR) circuit that makes sure all the registers start with default or user-programmed settings using NVM. The AFE539F1-Q1 operates with either an internal reference, external reference, or with power supply as the reference.

The AFE539F1-Q1 supports I^2C standard mode (100Kbps), fast mode (400Kbps), and fast mode plus (1Mbps). The I^2C interface can be configured with four device addresses using the A0 pin. The SPI mode supports a three-wire interface by default, with up to 25-MHz SCLK input. The NC/SDO input can be configured as SDO in the NVM for SPI read capability. The AFE539F1-Q1 is designed for constant power dissipation in automotive DC-link capacitor discharge circuits and constant power heating applications. The state machine and NVM enable *processor-less* operation. Because of the *smart* feature set, the AFE539F1-Q1 is called a smart AFE.

7.2 Functional Block Diagram

Product Folder Links: *AFE539F1-Q1*
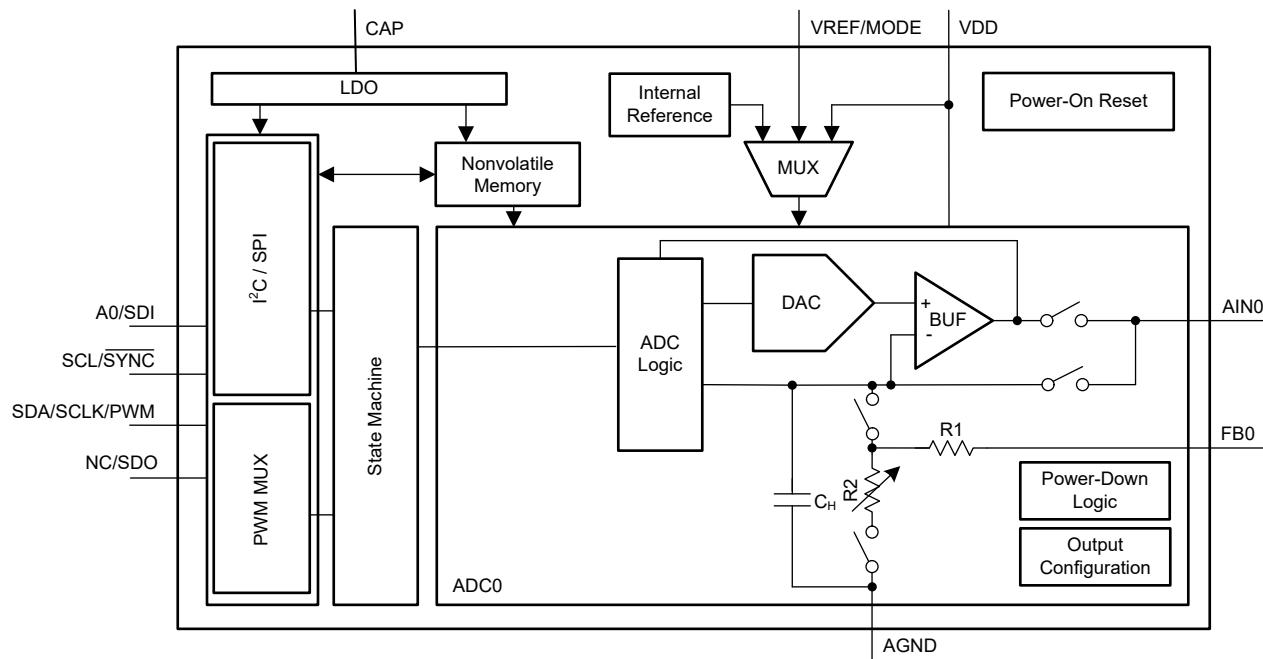
7.3 Feature Description

7.3.1 Smart Analog Front End (AFE) Architecture

The AFE539F1-Q1 smart analog front end (AFE) consists of a 10-bit analog-to-digital converter (ADC) input and a 7-bit duty-cycle pulse-width modulation (PWM) output. The ADC uses a successive-approximation register (SAR) architecture. The DAC inside the ADC uses a string architecture. The PWM output is multiplexed with one of the digital interface pins. Section 7.2 shows the smart AFE architecture within the block diagram, which operates from a 1.8-V to 5.5-V power supply. The device has an internal voltage reference of 1.21 V. There is an option to select an external reference on the VREF/MODE pin or use the power supply as a reference. The ADC uses one of these three reference options.

The AFE539F1-Q1 features a preprogrammed state machine supporting constant power-dissipation control operation. Figure 7-1 shows the digital architecture of the smart AFE with the interconnections between different functional blocks. This state machine allows the user to program the coefficients and input-output parameters. The state machine can be disabled by writing to the STATE-MACHINE-CONFIG0 register. The user configurations are stored in the NVM and the state machine can be operated in standalone mode without interfacing to a processor (*processor-less* operation).
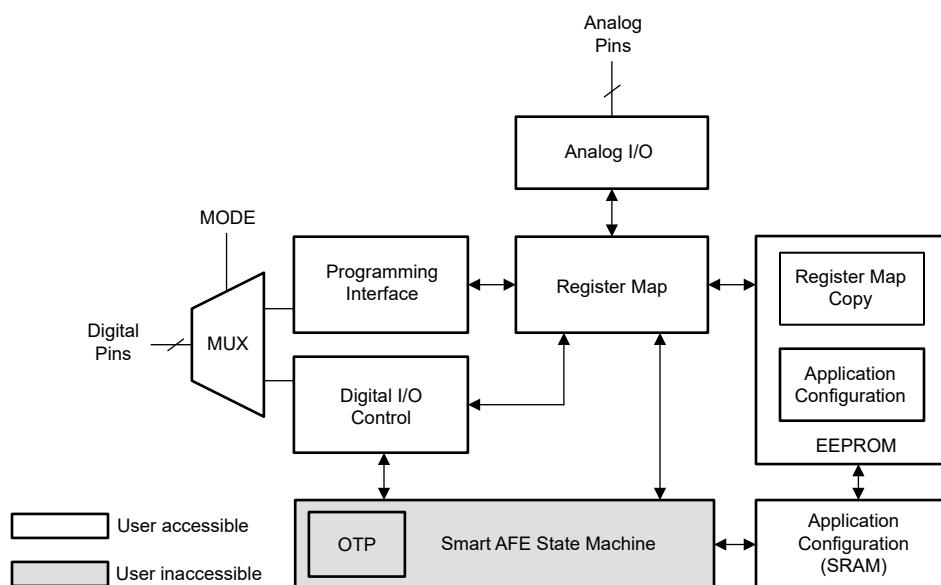

Figure 7-1. Smart AFE Architecture

7.3.2 Programming Interface

The AFE539F1-Q1 have five digital I/O pins that control I^{2}C, SPI, PWM, and mode selection. The VREF/MODE pin must be at logic low to enable the programming interface. These devices automatically detect I^{2}C and SPI protocols at the first successful communication after power-on, and then connect to the detected interface. After an interface protocol is connected, any change in the protocol is ignored. The I^{2}C interface uses the A0 pin to select from among four address options. The SPI is a three-wire interface by default. No readback capability is available in three-wire SPI mode. The NC/SDO pin can be configured as the SDO function in the register map and then programmed into the NVM. With the NC/SDO pin acting as SDO, the SPI works as a four-wire interface. The SPI readback mode is slower than the write mode. The programming interface pins are:

- I^{2}C: SCL, SDA, A0
- SPI: SCLK, SDI, $\overline{\text{SYNC}}$, NC/SDO

All the digital pins are open drain when used as outputs. Therefore, all the output pins must be pulled up to the desired I/O voltage using external resistors.

7.3.3 Nonvolatile Memory (NVM)

The AFE539F1-Q1 contain nonvolatile memory (NVM) bits. These memory bits are user programmable and erasable, and retain set values in the absence of a power supply. The highlighted gray cells in the *Register Map* show all the register bits that can be stored in the NVM by setting NVM-PROG = 1 in the COMMON-TRIGGER register. The NVM-PROG bit autoresets. The NVM-BUSY bit in the GENERAL-STATUS register is set to 1 by the device when an NVM write or reload operation is ongoing. During this time, the device blocks all read and write operations from and to the device. The NVM-BUSY bit is set to 0 after the write or reload operation is complete; at this point, all read and write operations from and to the device are allowed. The default value for all the registers in the AFE539F1-Q1 is loaded from NVM as soon as a POR event is issued.

The AFE539F1-Q1 also implements a NVM-RELOAD bit in the COMMON-TRIGGER register. Set this bit to 1 for the device to start an NVM-reload operation. The NVM-reload operation overwrites the register map with the stored data from the NVM. After completion, the device autoresets this bit to 0. During the NVM-RELOAD operation, the NVM-BUSY bit is set to 1.

7.3.3.1 NVM Cyclic Redundancy Check (CRC)

The AFE539F1-Q1 implements a cyclic redundancy check (CRC) feature for the NVM to make sure that the data stored in the NVM is uncorrupted. There are two types of CRC alarm bits implemented in the AFE539F1-Q1:

- NVM-CRC-FAIL-USER
- NVM-CRC-FAIL-INT

The NVM-CRC-FAIL-USER bit indicates the status of user-programmable NVM bits, and the NVM-CRC-FAIL-INT bit indicates the status of internal NVM bits. The CRC feature is implemented by storing a 16-bit CRC (CRC-16-CCITT) along with the NVM data each time the NVM program operation (write or reload) is performed and during the device boot up. The device reads the NVM data and validates the data with the stored CRC. The CRC alarm bits (NVM-CRC-FAIL-USER and NVM-CRC-FAIL-INT in the GENERAL-STATUS register) report any errors after the data are read from the device NVM. The alarm bits are set only at boot up.

7.3.3.1.1 NVM-CRC-FAIL-USER Bit

A logic 1 on NVM-CRC-FAIL-USER bit indicates that the user-programmable NVM data are corrupt. During this condition, all registers in the device are initialized with factory reset values, and any registers can be written to or read from. To reset the alarm bits to 0, issue a software reset (see *Section 7.3.5*) command, or cycle power to the device. A software reset or power-cycle also reloads the user-programmable NVM bits. In case the failure persists, reprogram the NVM.

7.3.3.1.2 NVM-CRC-FAIL-INT Bit

A logic 1 on NVM-CRC-FAIL-INT bit indicates that the internal NVM data are corrupt. During this condition, all registers in the device are initialized with factory reset values, and any registers can be written to or read from. In case of a temporary failure, to reset the alarm bits to 0, issue a software reset (see *Section 7.3.5*) command or cycle power to the device. A permanent failure in the NVM makes the device unusable.

7.3.4 Power-On Reset (POR)

The AFE539F1-Q1 includes a power-on reset (POR) function that controls the output voltage at power up. After the V_{DD} supply has been established, a POR event is issued. The POR causes all registers to initialize to default values, and communication with the device is valid only after a POR (boot-up) delay. The default value for all the registers in the AFE539F1-Q1 is loaded from NVM as soon as the POR event is issued.

When the device powers up, a POR circuit sets the device to the default mode. The POR circuit requires specific V_{DD} levels, as indicated in Figure 7-2, to make sure that the internal capacitors discharge and reset the device at power up. To make sure that a POR occurs, V_{DD} must be less than 0.7 V for at least 1 ms. When V_{DD} drops to less than 1.65 V, but remains greater than 0.7 V (shown as the undefined region), the device may or may not reset under all specified temperature and power-supply conditions. In this case, initiate a POR. When V_{DD} remains greater than 1.65 V, a POR does not occur.
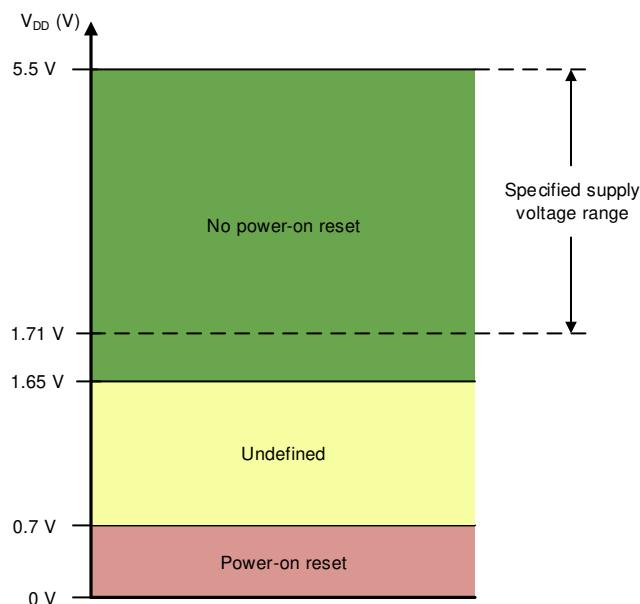
Figure 7-2. Threshold Levels for V_{DD} POR Circuit

7.3.5 External Reset

An external reset to the device can be triggered through the register map. To initiate a device software reset event, write the reserved code 1010b to the RESET field in the COMMON-TRIGGER register. A software reset initiates a POR event.

7.3.6 Register-Map Lock

The AFE539F1-Q1 implements a register-map lock feature that prevents an accidental or unintended write to the registers. The device locks all the registers when the DEV-LOCK bit in the COMMON-CONFIG register is set to 1. However, the software reset function through the COMMON-TRIGGER register is not blocked when using I^{2}C interface. To bypass the DEV-LOCK setting, write 0101b to the DEV-UNLOCK bits in the COMMON-TRIGGER register.

7.4 Device Functional Modes

7.4.1 Analog-to-Digital Converter (ADC) Mode

Channel 0 of the AFE539F1-Q1 acts as an ADC. The ADC is controlled by the state-machine in this device. The transfer function of the ADC is given in Equation 1.

$$\text{ADC\_DATA} = \left(\text{INTEGER}\right)\left(\frac{V_{IN}}{V_{FS}}\right) \times 2^{N} \tag{1}$$

where:

- ADC_DATA is the output of the ADC available to the state machine and is limited to $(2^{N}-1)$.
- V_{IN} is the input voltage at the AIN0 pin.
- V_{FS} is the full-scale input voltage, as provided in Table 7-1.
- N is the number of ADC bits = 10.
- INTEGER denotes integer division.

Table 7-1. Full Scale Analog Input (V_{FS})

REFERENCE (VREF)	GAIN	V_{FS}
Power supply	1 ×	VDD / 3
External	1 ×	VREF / 3
Internal	1.5 ×	(VREF × GAIN) / 3
	2 ×	(VREF × GAIN) / 3
	3 ×	(VREF × GAIN) / 6
	4 ×	(VREF × GAIN) / 6

7.4.1.1 Voltage Reference Selection

Figure 7-3 shows the three possible voltage reference options with the AFE539F1-Q1: the power supply as reference, internal reference, or external reference (VREF/MODE pin). The REF-GAIN field in the REF-GAIN-CONFIG register selects the reference and the respective gain. The full scale ADC voltage changes based on the voltage reference selection.
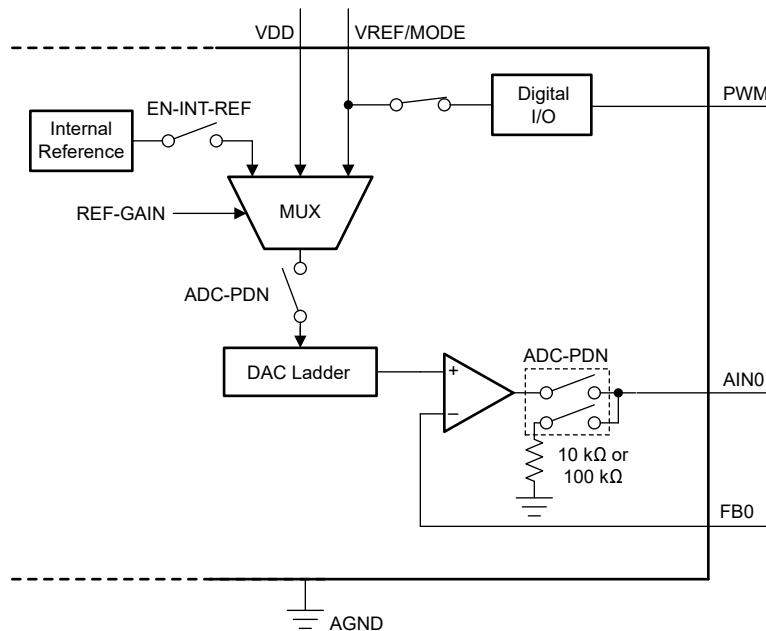
Figure 7-3. Voltage Reference Selection and Power-Down Logic

7.4.1.1.1 Power-Supply as Reference

By default, the AFE539F1-Q1 operates with the power-supply pin (VDD) as a reference. The gain at the output stage is always 1 ×.

7.4.1.1.2 Internal Reference

The AFE539F1-Q1 contains an internal reference. To enable the internal reference, write 1 to the EN-INT-REF bit in the COMMON-CONFIG register. The internal reference generates a fixed 1.21-V voltage (typical). Use the REF-GAIN field in the REF-GAIN-CONFIG register to select the internal reference and also to achieve gains of 1.5 ×, 2 ×, 3 ×, or 4 × for the ADC full scale voltage (V_{FS}).

7.4.1.1.3 External Reference

The AFE539F1-Q1 provides an external reference input. Select the external reference option by configuring the REF-GAIN field in the REF-GAIN-CONFIG register appropriately. The external reference can be between 1.8 V and VDD.

Note

The external reference must be less than VDD in both transient and steady-state conditions. Therefore, the external reference must ramp up after VDD and ramp down before VDD.

7.4.2 Pulse-Width Modulation (PWM) Mode

The AFE539F1-Q1 provides the 7-bit duty-cycle PWM output on the SDA/SCLK/PWM pin. Pull the VREF/MODE pin high to enable PWM functionality. Table 7-2 lists all the possible PWM frequency configurations using the PWM-FREQ bits in the PWM-FREQUENCY SRAM register.

Table 7-2. PWM Frequency Configuration

SRAM REGISTER	PWM-FREQ BIT FIELD	PWM FREQUENCY (kHz)	DUTY CYCLE (%) FOR CODE 1	DUTY CYCLE (%) FOR CODE 126
PWM-FREQUENCY (0x23 [4:0])	0	Invalid	N/A	N/A
	1	48.828	4.88	95.12
	2	24.414	2.44	97.56
	3	16.276	1.63	98.37
	4	12.207	1.22	98.44
	5	8.138	0.81	98.44
	6	6.104	0.78	98.44
	7	3.052	0.78	98.44
	8	2.035	0.78	98.44
	9	1.526	0.78	98.44
	10	1.221	0.78	98.44
	11	1.017	0.78	98.44
	12	0.872	0.78	98.44
	13	0.763	0.78	98.44
	14	0.678	0.78	98.44
	15	0.610	0.78	98.44
	16	0.555	0.78	98.44
	17	0.509	0.78	98.44
	18	0.470	0.78	98.44
	19	0.436	0.78	98.44
	20	0.407	0.78	98.44
	21	0.381	0.78	98.44
	22	0.359	0.78	98.44
	23	0.339	0.78	98.44
	24	0.321	0.78	98.44
	25	0.305	0.78	98.44
	26	0.291	0.78	98.44
	27	0.277	0.78	98.44
	28	0.265	0.78	98.44
	29	0.254	0.78	98.44
	30	0.244	0.78	98.44
	31	0.218	0.78	98.44

The duty cycle of the PWM is proportional to the 7-bit code, 0d to 126d. As Table 7-3 shows, the code 127d corresponds to 100% duty cycle. The duty cycle 99.22% (127d/128d) is skipped to achieve 100% duty cycle using a 7-bit code. The PWM duty-cycle setting is done by the state machine and is not exposed to the user.

Table 7-3. PWM Duty Cycle Setting

CODE	DUTY-CYCLE	DESCRIPTION
0	0%	Always 0
1	0.78%	Minimum linear duty cycle
x	(x/128)%	x is the code between 2d and 125d, both included
126	98.44%	Maximum linear duty cycle
127	100%	Always 1. The duty cycle 99.22% (127d/128d) is skipped.

Product Folder Links: *AFE539F1-Q1*

7.4.3 Constant Power-Dissipation Control

The AFE539F1-Q1 can be used in applications where constant power dissipation is desired on a resistive load independently on applied voltage. Power dissipation in a fixed resistive load is inversely proportional to the resistance. When the voltage across the resistance varies, for example, in a discharging circuit, constant power can be achieved by modulating the effective resistance seen by the discharge circuit. Figure 7-4 shows an example circuit to create a variable effective resistance from a fixed resistive load using a PWM signal. The effective resistance is the load resistance divided by the PWM duty cycle.
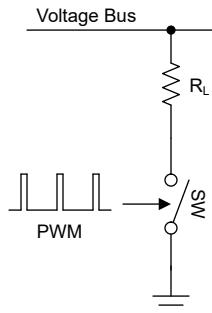
Figure 7-4. PWM-modulated Resistor

The AFE539F1-Q1 generates a PWM signal with a duty cycle dependent on the voltage applied to the ADC input. The AFE539F1-Q1 has a 10-bit ADC input with selectable reference voltage (V_{REF}). The AFE539F1-Q1 calculates the PWM duty cycle so that a constant dissipated power of the resistor is maintained.

The AFE539F1-Q1 runs a PWM duty cycle update loop that sets the duty cycle (D) according to Equation 2.

$$D = \frac{K \times 2^{15}}{(ADC\_DATA)^2} = \frac{K \times (V_{FS})^2}{(V_{IN})^2 \times 2^5} \tag{2}$$

where:

- ADC_DATA is the decimal equivalent of the output from the ADC available to the state machine.
- V_{IN} is the ADC input voltage.
- V_{FS} is the full-scale ADC input voltage, as listed in Table 7-1.
- K is a user-configurable function-coefficient with a value of 16-bit integer (range: 1 to 65535) as programmed in the FUNCTION-COEFFICIENT register.

The duty cycle of the PWM output of the AFE539F1-Q1 has 7-bit resolution which means the minimum duty cycle as well as the step size is about 0.78%. The PWM can achieve 100% saturation, the lower and upper PWM value limit is user-configurable as well to accommodate specific application requirements. The constant power achieved with this pulse-width modulated resistor can be expressed accordingly as Equation 3.

$$P_{const} = \frac{K_2 \times (V_{FS})^2}{R_L} \tag{3}$$

where:

- R_L is the load resistance.
- K_2 is a constant that is a function of the function-coefficient, K and the attenuation factor between the bus voltage and the full-scale ADC input.

Equation 3 expresses that the theoretical constant power is independent on the input voltage. The power depends on the load resistance value and value of the constant, K_2. However, the PWM is updated in discrete steps, the calculated constant power is in reality a power limit.

Product Folder Links: *AFE539F1-Q1*

7.5 Programming

7.5.1 SPI Programming Mode

An SPI access cycle for AFE539F1-Q1 is initiated by asserting the $\overline{\text{SYNC}}$ pin low. The serial clock, SCLK, can be a continuous or gated clock. SDI data are clocked on SCLK falling edges. The SPI frame for AFE539F1-Q1 is 24 bits long. Therefore, the $\overline{\text{SYNC}}$ pin must stay low for at least 24 SCLK falling edges. The access cycle ends when the $\overline{\text{SYNC}}$ pin is deasserted high. If the access cycle contains less than the minimum clock edges, the communication is ignored. By default, the SDO pin is not enabled (three-wire SPI). In the three-wire SPI mode, if the access cycle contains more than the minimum clock edges, only the first 24 bits are used by the device. When $\overline{\text{SYNC}}$ is high, the SCLK and SDI signals are blocked, and SDO becomes Hi-Z to allow data readback from other devices connected on the bus.

Table 7-4 and Figure 7-5 describe the format for the 24-bit SPI access cycle. The first byte input to SDI is the instruction cycle. The instruction cycle identifies the request as a read or write command and the 7-bit address that is to be accessed. The last 16 bits in the cycle form the data cycle.

Table 7-4. SPI Read/Write Access Cycle

BIT	FIELD	DESCRIPTION
23	R/$\overline{\text{W}}$	Identifies the communication as a read or write command to the address register: R/$\overline{\text{W}}$ = 0 sets a write operation. R/$\overline{\text{W}}$ = 1 sets a read operation
22-16	A[6:0]	Register address: specifies the register to be accessed during the read or write operation
15-0	DI[15:0]	Data cycle bits: If a write command, the data cycle bits are the values to be written to the register with address A[6:0]. If a read command, the data cycle bits are *don't care* values.
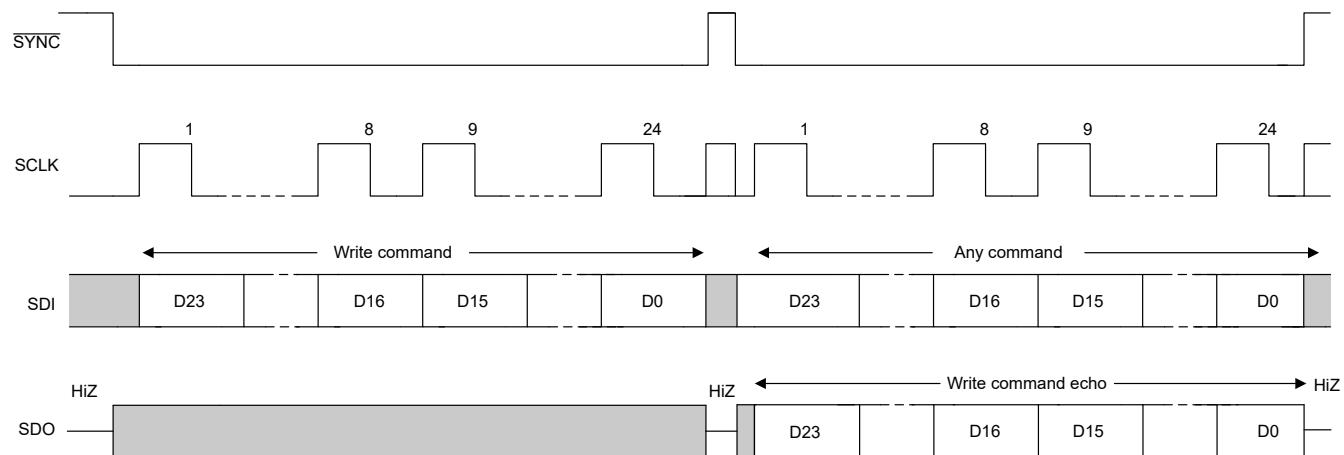
Figure 7-5. SPI Write Cycle

Read operations require that the SDO pin is first enabled by setting the SDO-EN bit in the INTERFACE-CONFIG register. This configuration is called four-wire SPI. A read operation is initiated by issuing a read command access cycle. After the read command, a second access cycle must be issued to get the requested data. The output data format is shown in Table 7-5 and Figure 7-6. Data are clocked out on the SDO pin either on the falling edge or rising edge of SCLK according to the FSDO bit, as shown in Figure 6-3.

Table 7-5. SDO Output Access Cycle

BIT	FIELD	DESCRIPTION
23	R/$\overline{\text{W}}$	Echo R/$\overline{\text{W}}$ from previous access cycle
22-16	A[6:0]	Echo register address from previous access cycle
15-0	DI[15:0]	Readback data requested on previous access cycle

Product Folder Links: *AFE539F1-Q1*
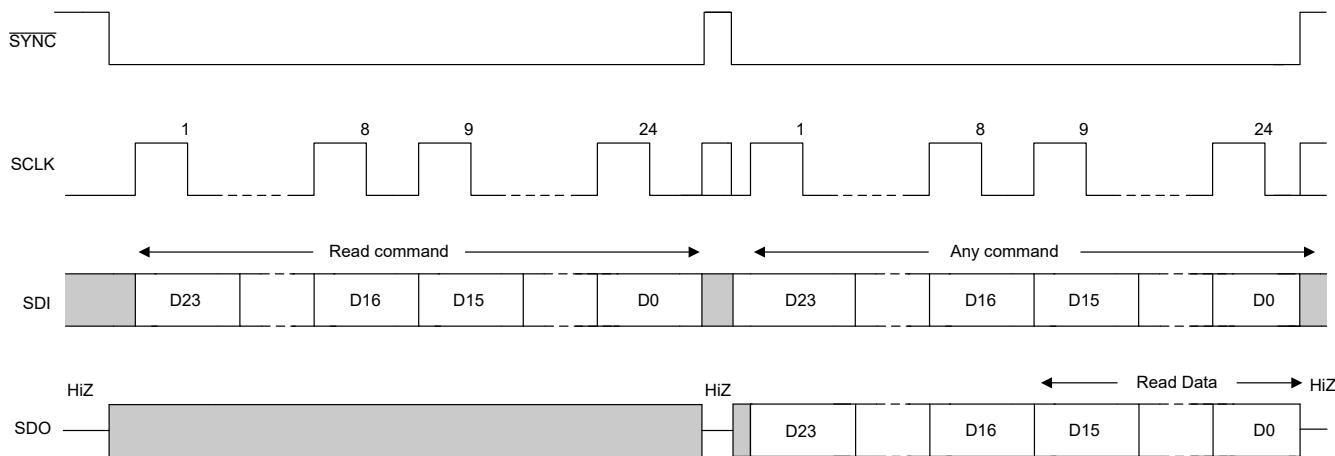
Figure 7-6. SPI Read Cycle

The daisy-chain operation is also enabled with the SDO pin. In daisy-chain mode, multiple devices are connected in a *chain* with the SDO pin of one device is connected to SDI pin of the following device, as shown in Figure 7-7. The SPI host drives the SDI pin of the first device in the chain. The SDO pin of the last device in the chain is connected to the POCI pin of the SPI host. In four-wire SPI mode, if the access cycle contains multiples of 24 clock edges, only the last 24 bits are used by the device first device in the chain. If the access cycle contains clock edges that are not in multiples of 24, the SPI packet is ignored by the device. Figure 7-8 describes the packet format for the daisy-chain write cycle.
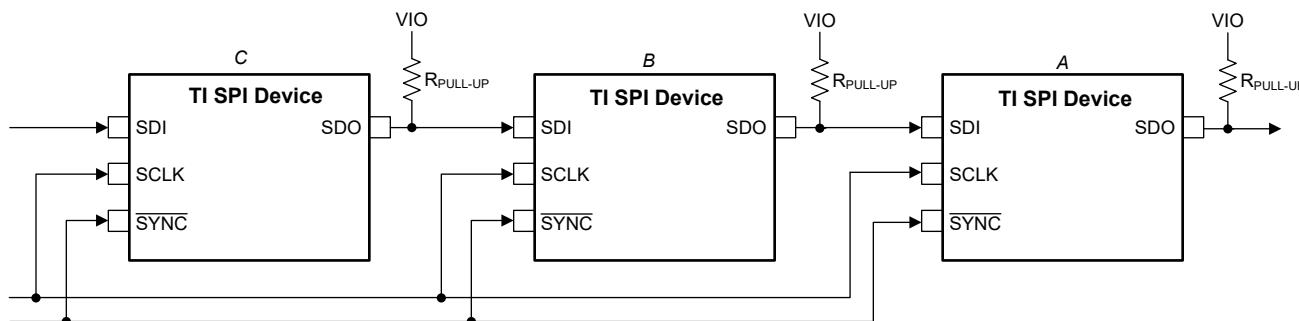
Figure 7-7. SPI Daisy-Chain Connection
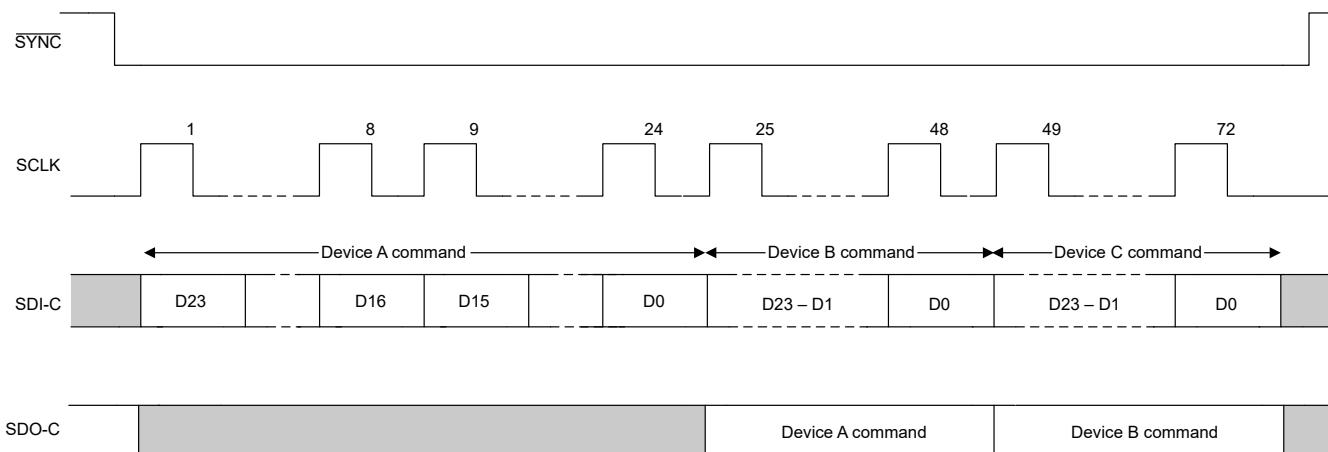
Figure 7-8. SPI Daisy-Chain Write Cycle

Product Folder Links: *AFE539F1-Q1*

7.5.2 I²C Programming Mode

The AFE539F1-Q1 has a 2-wire serial interface (SCL and SDA), and one address pin (A0), as shown in the pin diagram in the *Pin Configuration and Functions* section. The I²C bus consists of a data line (SDA) and a clock line (SCL) with pullup structures. When the bus is idle, both SDA and SCL lines are pulled high. All the I²C-compatible devices connect to the I²C bus through the open drain I/O pins, SDA and SCL.

The I²C specification states that the device that controls communication is called a *controller*, and the devices that are controlled by the controller are called *targets*. The controller generates the SCL signal. The controller also generates special timing conditions (start condition, repeated start condition, and stop condition) on the bus to indicate the start or stop of a data transfer. Device addressing is completed by the controller. The controller on an I²C bus is typically a microcontroller or digital signal processor (DSP). The AFE539F1-Q1 operates as a target on the I²C bus. A target acknowledges controller commands, and upon controller control, receives or transmits data.

Typically, the AFE539F1-Q1 operates as a target receiver. A controller writes to the AFE539F1-Q1, a target receiver. However, if a controller requires the AFE539F1-Q1 internal register data, the AFE539F1-Q1 operates as a target transmitter. In this case, the controller reads from the AFE539F1-Q1. According to I²C terminology, read and write refer to the controller.

The AFE539F1-Q1 supports the following data transfer modes:

• Standard mode (100Kbps)
• Fast mode (400Kbps)
• Fast mode plus (1.0Mbps)

The data transfer protocol for standard and fast modes is exactly the same; therefore, both modes are referred to as *F/S-mode* in this document. The fast mode plus protocol is supported in terms of data transfer speed, but not output current. The low-level output current is 3 mA; similar to the case of standard and fast modes. The AFE539F1-Q1 supports 7-bit addressing. The 10-bit addressing mode is not supported. The device supports the general call reset function. Sending the following sequence initiates a software reset within the device: start or repeated start, 0x00, 0x06, stop. The reset is asserted within the device on the rising edge of the ACK bit, following the second byte.

Other than specific timing signals, the I²C interface works with serial bytes. At the end of each byte, a ninth clock cycle generates and detects an acknowledge signal. An acknowledge is when the SDA line is pulled low during the high period of the ninth clock cycle. A not-acknowledge is when the SDA line is left high during the high period of the ninth clock cycle, as shown in Figure 7-9.
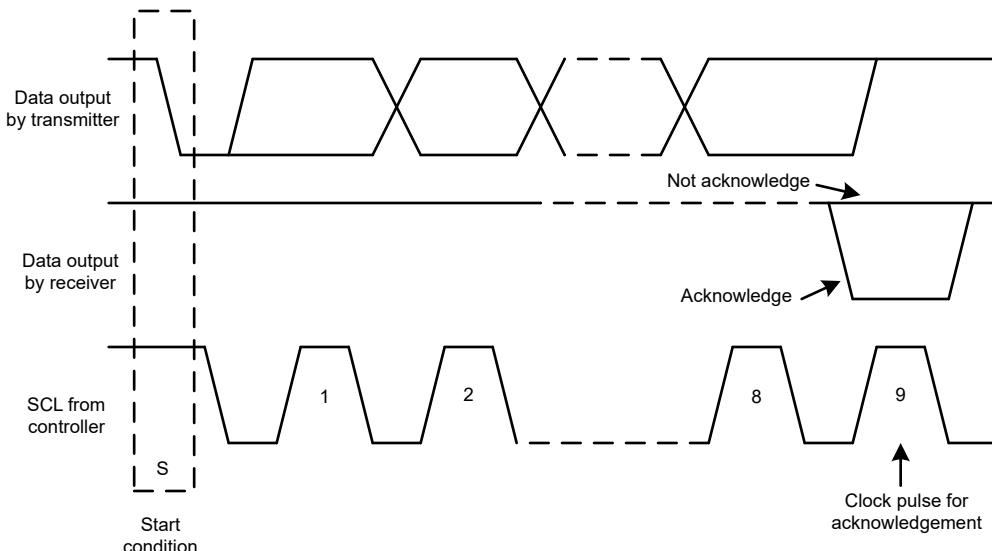
Figure 7-9. Acknowledge and Not Acknowledge on the I²C Bus

Product Folder Links: *AFE539F1-Q1*

7.5.2.1 F/S Mode Protocol

The following steps explain a complete transaction in F/S mode.

1. The controller initiates data transfer by generating a start condition. The start condition is when a high-to-low transition occurs on the SDA line while SCL is high, as shown in Figure 7-10. All I2C-compatible devices recognize a start condition.
2. The controller then generates the SCL pulses, and transmits the 7-bit address and the read/write direction bit (R/$\overline{W}$) on the SDA line. During all transmissions, the controller makes sure that data are valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse, as shown in Figure 7-11. All devices recognize the address sent by the controller and compare the address to the respective internal fixed address. Only the target device with a matching address generates an acknowledge by pulling the SDA line low during the entire high period of the 9th SCL cycle, as shown in Figure 7-9. When the controller detects this acknowledge, the communication link with a target has been established.
3. The controller generates further SCL cycles to transmit (R/$\overline{W}$ bit 0) or receive (R/$\overline{W}$ bit 1) data to the target. In either case, the receiver must acknowledge the data sent by the transmitter. The acknowledge signal can be generated by the controller or by the target, depending on which is the receiver. The 9-bit valid data sequences consists of eight data bits and one acknowledge-bit, and can continue as long as necessary.
4. To signal the end of the data transfer, the controller generates a stop condition by pulling the SDA line from low-to-high while the SCL line is high, as shown in Figure 7-10. This action releases the bus and stops the communication link with the addressed target. All I2C-compatible devices recognize the stop condition. Upon receipt of a stop condition, the bus is released, and all target devices then wait for a start condition followed by a matching address.
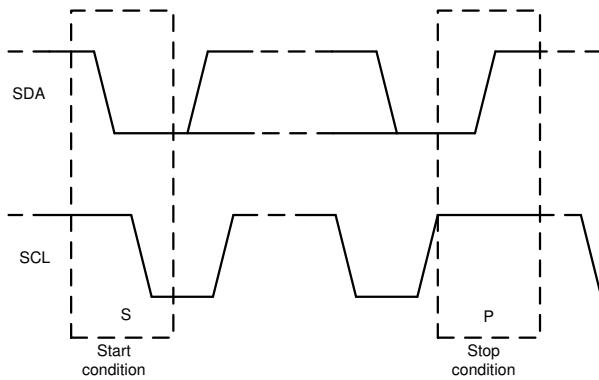
Figure 7-10. Start and Stop Conditions
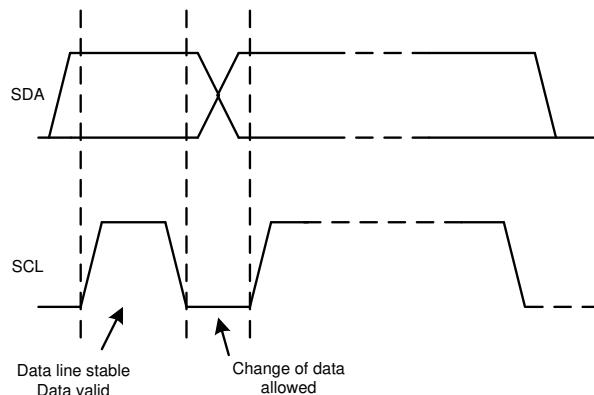
Figure 7-11. Bit Transfer on the I2C Bus

Product Folder Links: *AFE539F1-Q1*

7.5.2.2 I²C Update Sequence

For a single update, the AFE539F1-Q1 requires a start condition, a valid I²C address byte, a command byte, and two data bytes, as listed in Table 7-6.

Table 7-6. Update Sequence

MSB	....	LSB	ACK	MSB	...	LSB	ACK	MSB	...	LSB	ACK	MSB	...	LSB	ACK
Address (A) byte Section 7.5.2.2.1				Command byte Section 7.5.2.2.2				Data byte - MSDB				Data byte - LSDB			
DB [31:24]				DB [23:16]				DB [15:8]				DB [7:0]			

After each byte is received, the AFE539F1-Q1 acknowledges the byte by pulling the SDA line low during the high period of a single clock pulse, as shown in Figure 7-12. These four bytes and acknowledge cycles make up the 36 clock cycles required for a single update to occur. A valid I²C address byte selects the AFE539F1-Q1.
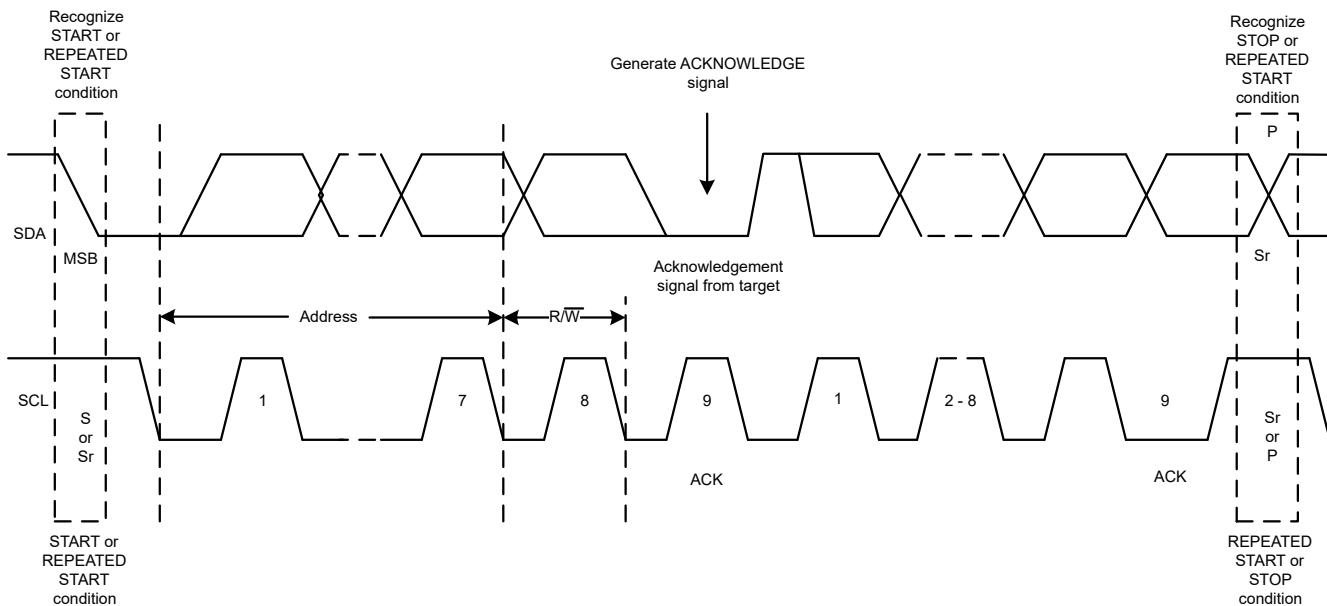
Figure 7-12. I²C Bus Protocol

The command byte sets the operating mode of the selected AFE539F1-Q1 device. For a data update to occur when the operating mode is selected by this byte, the AFE539F1-Q1 device must receive two data bytes: the most significant data byte (MSDB) and least significant data byte (LSDB). The AFE539F1-Q1 device performs an update on the falling edge of the acknowledge signal that follows the LSDB.

When using fast mode (clock = 400 kHz), the maximum update rate is limited to 10Ksps. Using fast mode plus (clock = 1 MHz), the maximum update rate is limited to 25Ksps. When a stop condition is received, the AFE539F1-Q1 device releases the I²C bus and awaits a new start condition.

7.5.2.2.1 Address Byte

The address byte, as shown in Table 7-7, is the first byte received from the controller device following the start condition. The first four bits (MSBs) of the address are factory preset to 1001. The next three bits of the address are controlled by the A0 pin. The A0 pin input can be connected to VDD, AGND, SCL, or SDA. The A0 pin is sampled during the first byte of each data frame to determine the address. The device latches the value of the address pin, and consequently responds to that particular address according to Table 7-8.

Table 7-7. Address Byte

COMMENT	MSB							LSB
—	AD6	AD5	AD4	AD3	AD2	AD1	AD0	R/$\overline{W}$
General address	1	0	0	1	See Table 7-8 (target address column)			0 or 1
Broadcast address	1	0	0	0	1	1	1	0

Table 7-8. Address Format

TARGET ADDRESS	A0 PIN
000	AGND
001	VDD
010	SDA
011	SCL

The AFE539F1-Q1 supports broadcast addressing, which is used for synchronously updating or powering down multiple AFE539F1-Q1 devices. When the broadcast address is used, the AFE539F1-Q1 responds regardless of the address pin state. Broadcast is supported only in write mode.

7.5.2.2.2 Command Byte

The *Register Names* table in the *Register Map* section lists the command byte in the ADDRESS column.

7.5.2.3 I²C Read Sequence

To read any register the following command sequence must be used:

1. Send a start or repeated start command with a target address and the R/$\overline{W}$ bit set to 0 for writing. The device acknowledges this event.
2. Send a command byte for the register to be read. The device acknowledges this event again.
3. Send a repeated start with the target address and the R/$\overline{W}$ bit set to 1 for reading. The device acknowledges this event.
4. The device writes the MSDB byte of the addressed register. The controller must acknowledge this byte.
5. Finally, the device writes out the LSDB of the register.

The broadcast address cannot be used for reading.

Table 7-9. Read Sequence

S	MSB	...	R/$\overline{W}$ (0)	ACK	MSB	...	LSB	ACK	Sr	MSB	...	R/$\overline{W}$ (1)	ACK	MSB	...	LSB	ACK	MSB	...	LSB	ACK
	ADDRESS BYTE Section 7.5.2.2.1				COMMAND BYTE Section 7.5.2.2.2				Sr	ADDRESS BYTE Section 7.5.2.2.1				MSDB				LSDB			
	From Controller			Target	From Controller			Target		From Controller			Target	From Target			Controller	From Target			Controller

7.6 Register Maps

Table 7-10. Register Map

REGISTER	BIT15	BIT14	BIT13	BIT12	BIT11	BIT10	BIT9	BIT8	BIT7	BIT6	BIT5	BIT4	BIT3	BIT2	BIT1	BIT0
	MOST SIGNIFICANT DATA BYTE (MSDB)								LEAST SIGNIFICANT DATA BYTE (LSDB)							
NOP	NOP															
REF-GAIN-CONFIG	X			REF-GAIN			RESERVED									
COMMON-CONFIG	RESERVED	DEV-LOCK	RESERVED	EN-INT-REF	ADC-PDN		RESERVED									
COMMON-TRIGGER	DEV-UNLOCK					RESET			RESERVED						NVM-PROG	NVM-RELOAD
COMMON-PWM-TRIG	RESERVED															START-FUNCTION
GENERAL-STATUS	NVM-CRC-FAIL-INT	NVM-CRC-FAIL-USER	RESERVED					NVM-BUSY	DEVICE-ID						VERSION-ID	
INTERFACE-CONFIG	X			TIMEOUT-EN	X									FSDO-EN	X	SDO-EN
STATE-MACHINE-CONFIG0	RESERVED													SM-ABORT	SM-START	SM-EN
SRAM-CONFIG	X								SRAM-ADDR							
SRAM-DATA	SRAM-DATA															
MAX-OUTPUT	RESERVED								MAX-OUTPUT							
MIN-OUTPUT	RESERVED								MIN-OUTPUT							
FUNCTION-COEFFICIENT	FUNCTION-COEFFICIENT															
PWM-FREQUENCY	RESERVED								PWM-FREQ							

Note: Shaded cells indicate the register bits or fields that are stored in NVM.

Note: X = Don't care.

Table 7-11. Register Names

I2C/SPI ADDRESS (COMMAND BYTE)	SRAM ADDRESS	REGISTER NAME	SECTION
00h	—	NOP	Section 7.6.1
15h	—	REF-GAIN-CONFIG	Section 7.6.2
1Fh	—	COMMON-CONFIG	Section 7.6.3
20h	—	COMMON-TRIGGER	Section 7.6.4
21h	—	COMMON-PWM-TRIG	Section 7.6.5
22h	—	GENERAL-STATUS	Section 7.6.6
26h	—	INTERFACE-CONFIG	Section 7.6.7
27h	—	STATE-MACHINE-CONFIG0	Section 7.6.8
2Bh	—	SRAM-CONFIG	Section 7.6.9
2Ch	—	SRAM-DATA	Section 7.6.10
—	20h	MAX-OUTPUT	Section 7.6.11
—	21h	MIN-OUTPUT	Section 7.6.12
—	22h	FUNCTION-COEFFICIENT	Section 7.6.13
—	23h	PWM-FREQUENCY	Section 7.6.14

7.6.1 NOP Register (address = 00h) [reset = 0000h]

Figure 7-13. NOP Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
							NOP								
							R/W-0h								

Table 7-12. NOP Register Field Descriptions

Bit	Field	Type	Reset	Description
15-0	NOP	R/W	0000h	No operation

7.6.2 REF-GAIN-CONFIG Register (address = 15h) [reset = 0401h]

Figure 7-14. REF-GAIN-CONFIG Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	X			REF-GAIN				RESERVED							
	X-0h			R/W-001				R/W-001h							

Table 7-13. REF-GAIN-CONFIG Register Field Descriptions

Bit	Field	Type	Reset	Description
15-13	X	X	0h	Don't care.
12-10	REF-GAIN	R/W	001	000: Gain = 1 ×, external reference on VREF/MODE pin. 001: Gain = 1 ×, VDD as reference (default). 010: Gain = 1.5 ×, internal reference. 011: Gain = 2 ×, internal reference. 100: Gain = 3 ×, internal reference. 101: Gain = 4 ×, internal reference. Others: NA.
9-0	RESERVED	R/W	001h	Always write 001h.

7.6.3 COMMON-CONFIG Register (address = 1Fh) [reset = 13FFh]

Figure 7-15. COMMON-CONFIG Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
RESERVED	DEV-LOCK	RESERVED	EN-INT-REF	ADC-PDN				RESERVED							
R/W-0h	R/W-0h	R/W-0h	R/W-1	R/W-0h				R/W-3FFh							

Table 7-14. COMMON-CONFIG Register Field Descriptions

Bit	Field	Type	Reset	Description
15	RESERVED	R/W	0	Always write 0.
14	DEV-LOCK	R/W	0	0: Device not locked 1: Device locked, the device locks all the registers. To set this bit back to 0 (unlock device), write to the unlock code to the DEV-UNLOCK field in the COMMON-TRIGGER register first, followed by a write to the DEV-LOCK bit as 0.
13	RESERVED	R/W	0	Always write 0.
12	EN-INT-REF	R/W	1	0: Disable internal reference 1: Enable internal reference. This bit must be set before using internal reference gain settings.
11	ADC-PDN	R/W	0	00: Power-up ADC. 01: Power-down ADC with 10 KΩ to AGND. 10: Power-down ADC with 100 KΩ to AGND. 11: Power-down ADC with Hi-Z to AGND.
10-0	RESERVED	R/W	3FFh	Always write 3FFh.

Product Folder Links: *AFE539F1-Q1*

7.6.4 COMMON-TRIGGER Register (address = 20h) [reset = 0000h]

Figure 7-16. COMMON-TRIGGER Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
DEV-UNLOCK				RESET				RESERVED						NVM-PROG	NVM-RELOAD
R/W-0h				R/W-0h				R/W-00h						R/W-0h	R/W-0h

Table 7-15. COMMON-TRIGGER Register Field Descriptions

Bit	Field	Type	Reset	Description
15-12	DEV-UNLOCK	R/W	0h	0101: Device unlocking password. Others: Don't care.
11-8	RESET	W	0h	1010: POR reset triggered. This field is self-resetting. Others: Don't care.
7-2	RESERVED	R/W	00h	Always write 0.
1	NVM-PROG	R/W	0	0: NVM write not triggered. 1: NVM write triggered. This bit is self-resetting.
0	NVM-RELOAD	R/W	0	0: NVM reload not triggered. 1: Reload data from NVM to register map. This bit is self-resetting.

7.6.5 COMMON-PWM-TRIG Register (address = 21h) [reset = 0001h]

Figure 7-17. COMMON-PWM-TRIG Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
RESERVED															START-FUNCTION
R/W-0000h															R/W-0h

Table 7-16. COMMON-PWM-TRIG Register Field Descriptions

Bit	Field	Type	Reset	Description
15-1	RESERVED	R/W	0000h	Always write 0000h.
0	START-FUNCTION	R/W	0	0: Stop PWM generation. 1: Invalid. This bit is automatically set by the state machine.

7.6.6 GENERAL-STATUS Register (address = 22h) [reset = 00h, DEVICE-ID, VERSION-ID]

Figure 7-18. GENERAL-STATUS Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
NVM-CRC-FAIL-INT	NVM-CRC-FAIL-USER	X					NVM-BUSY	DEVICE-ID						VERSION-ID	
R-0h	R-0h	X-00h					R-0h	R-0h						R-0h	

Table 7-17. GENERAL-STATUS Register Field Descriptions

Bit	Field	Type	Reset	Description
15	NVM-CRC-FAIL-INT	R	0	0: No CRC error in OTP. 1: Indicates a failure in OTP loading. A software reset or power-cycle can bring the device out of this condition in case of temporary failure.
14	NVM-CRC-FAIL-USER	R	0	0: No CRC error in NVM loading. 1: Indicates a failure in NVM loading. The register settings are corrupted. The device allows all operations during this error condition. Reprogram the NVM to get original state. A software reset brings the device out of this error condition.
13	X	X	00h	Don't care.
8	NVM-BUSY	R	0	0: NVM is available for read and write. 1: NVM is not available for read or write.
7-2	DEVICE-ID	R	19h	Device identifier.
1-0	VERSION-ID	R	0	Version identifier.

7.6.7 INTERFACE-CONFIG Register (address = 26h) [reset = 0000h]

Figure 7-19. INTERFACE-CONFIG Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
X			TIMEOUT-EN	X									FSDO-EN	X	SDO-EN
X-0h			R/W-0h	X-0h									R/W-0h	X-0h	R/W-0h

Table 7-18. INTERFACE-CONFIG Register Field Descriptions

Bit	Field	Type	Reset	Description
15 - 13	X	X	0h	Don't care.
12	TIMEOUT-EN	R/W	0	0: I^{2}C timeout disabled. 1: I^{2}C timeout enabled.
11 - 3	X	X	0h	Don't care.
2	FSDO-EN	R/W	0	0: Fast SDO disabled. 1: Fast SDO enabled.
1	X	X	0	Don't care.
0	SDO-EN	R/W	0	0: SDO disabled. 1: SDO enabled.

Product Folder Links: *AFE539F1-Q1*

7.6.8 STATE-MACHINE-CONFIG0 Register (address = 27h) [reset = 0003h]

Figure 7-20. STATE-MACHINE-CONFIG0 Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
RESERVED													SM-ABORT	SM-START	SM-EN
R/W-0h													R/W-0h	R/W-0h	R/W-0h

Table 7-19. STATE-MACHINE-CONFIG0 Register Field Descriptions

Bit	Field	Type	Reset	Description
15 - 3	RESERVED	R/W	0000h	Always write 0.
2	SM-ABORT	R/W	0	0: State machine not aborted. 1: State machine aborted.
1	SM-START	R/W	0	0: State machine stopped. 1: State machine started. The state machine must be enabled using the SM-EN bit.
0	SM-EN	R/W	0	0: State machine disabled. 1: State machine enabled.

7.6.9 SRAM-CONFIG Register (address = 2Bh) [reset = 0000h]

Figure 7-21. SRAM-CONFIG Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
X								SRAM-ADDR							
X-00h								R/W-00h							

Table 7-20. SRAM-CONFIG Register Field Descriptions

Bit	Field	Type	Reset	Description
15-8	X	X	00h	Don't care
7-0	SRAM-ADDR	R/W	00h	8-bit SRAM address. Writing to this register field configures the SRAM address to be accessed next. This address automatically increments after a write to the SRAM.

7.6.10 SRAM-DATA Register (address = 2Ch) [reset = 0000h]

Figure 7-22. SRAM-DATA Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
SRAM-DATA															
R/W-0000h															

Table 7-21. SRAM-DATA Register Field Descriptions

Bit	Field	Type	Reset	Description
15-0	SRAM-DATA	R/W	0000h	16-bit SRAM data. Data are written to or read from the address configured in the SRAM-CONFIG register.

7.6.11 MAX-OUTPUT Register (SRAM address = 20h) [reset = 007Fh]

Note
This register address is mapped to SRAM. Use the SRAM-CONFIG and SRAM-DATA registers to read and write.

Figure 7-23. MAX-OUTPUT Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
RESERVED								MAX-OUTPUT							
R/W-0000h								R/W-7Fh							

Table 7-22. MAX-OUTPUT Register Field Descriptions

Bit	Field	Type	Reset	Description
15-7	RESERVED	R/W	0000h	Always write 0000h.
6-0	MAX-OUTPUT	R/W	7Fh	7-bit maximum limit for PWM output.

7.6.12 MIN-OUTPUT Register (SRAM address = 21h) [reset = 0000h]

Note
This register address is mapped to SRAM. Use the SRAM-CONFIG and SRAM-DATA registers to read and write.

Figure 7-24. MIN-OUTPUT Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
RESERVED								MIN-OUTPUT							
R/W-0000h								R/W-00h							

Table 7-23. MIN-OUTPUT Register Field Descriptions

Bit	Field	Type	Reset	Description
15-7	RESERVED	R/W	0000h	Always write 0000h.
6-0	MIN-OUTPUT	R/W	00h	7-bit minimum limit for PWM output.

7.6.13 FUNCTION-COEFFICIENT Register (SRAM address = 22h) [reset = 01F4h]

Note
This register address is mapped to SRAM. Use the SRAM-CONFIG and SRAM-DATA registers to read and write.

Figure 7-25. FUNCTION-COEFFICIENT Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
FUNCTION-COEFFICIENT															
R/W-01F4h															

Table 7-24. FUNCTION-COEFFICIENT Register Field Descriptions

Bit	Field	Type	Reset	Description
15-0	FUNCTION-COEFFICIENT	R/W	01F4h	16-bit function coefficient (K) as specified in Equation 2 and Equation 3.

7.6.14 PWM-FREQUENCY Register (SRAM address = 23h) [reset = 000Bh]

Note

This register address is mapped to SRAM. Use the SRAM-CONFIG and SRAM-DATA registers to read and write.

Figure 7-26. PWM-FREQUENCY Register

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
RESERVED											PWM-FREQ				
R/W-000h											R/W-0Bh				

Table 7-25. PWM-FREQUENCY Register Field Descriptions

Bit	Field	Type	Reset	Description
15-5	RESERVED	R/W	000h	Always write 000h.
15-0	SRAM-DATA	R/W	0Bh	5-bit PWM frequency setting as specified in Table 7-2.

Product Folder Links: *AFE539F1-Q1*

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The AFE539F1-Q1 is a smart analog front end (AFE) that includes an ADC channel, PWM output, NVM, internal reference, and are available in a tiny 3-mm × 3-mm package. The AFE539F1-Q1 have an integrated state machine that is pre-programmed as a constant power output controller. The ADC has a full-scale of VDD/3. Use an external attenuator when the input exceeds this range. The PWM provides a 7-bit duty-cycle output on the SDA/SCLK/PWM pin. Pull the VREF/MODE pin high to enable the PWM output. Pulling the VREF/MODE pin low enables the I^{2}C or SPI programming mode. The application parameters are programmed in the device using I^{2}C or SPI and stored in the NVM.

8.2 Typical Application

This design uses the AFE539F1-Q1 to maintain constant power dissipation on a restive load, independent of the applied voltage. Modulating the power resistor via a switch can change the effective resistance and maintain constant power as the supply voltage (V$_{BUS}$) changes. The AFE539F1-Q1 has an integrated state machine that converts the ADC input to a PWM output based on the transfer function in Equation 2. Parameters such as the PWM frequency, maximum and minimum duty cycle outputs, and the K term in Equation 2 are user programmable and can be saved in the NVM. The control loop runs standalone without the need for a processor after initial programming. Use this circuit in constant power heating, or automotive DC-link capacitor discharge applications. Figure 8-1 shows an example schematic for this application.
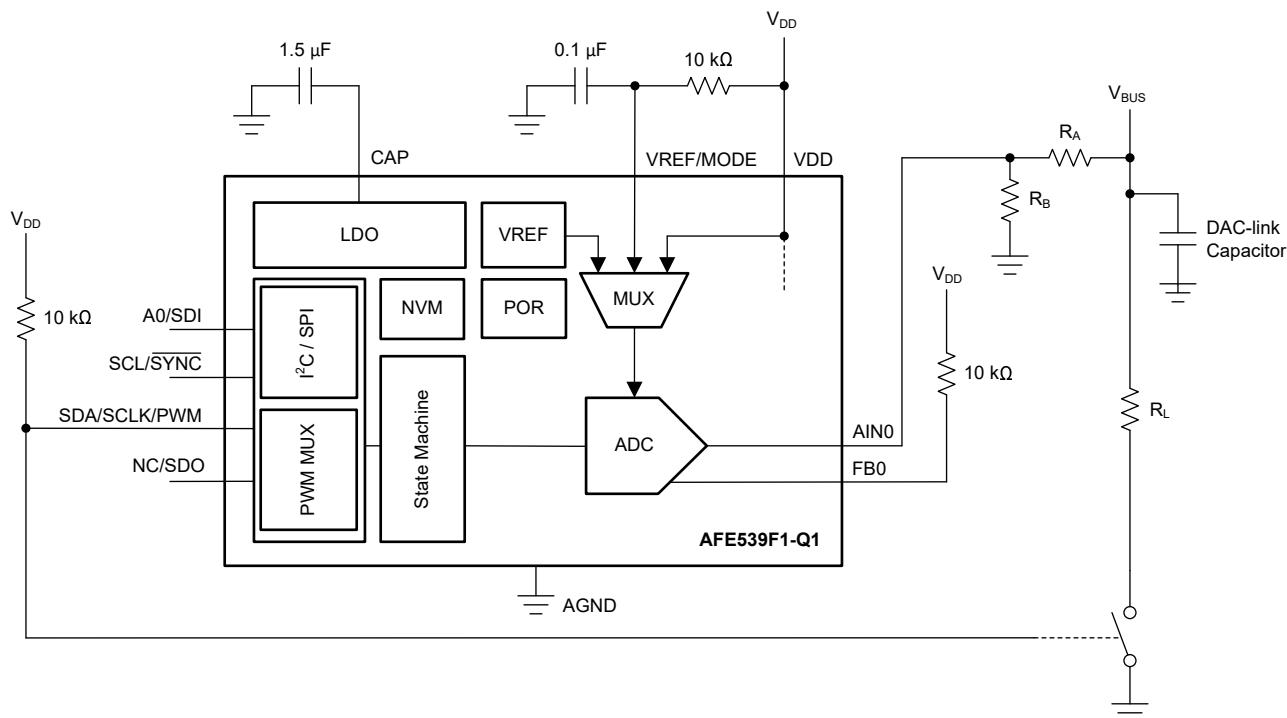
Constant Power Discharge Circuit

8.2.1 Design Requirements

Table 8-1. Design Parameters

PARAMETER	VALUE
PWM Frequency	3.052 kHz
Bus voltage (V_{BUS})	48 V
Load resistance (R_L)	5 Ω
Power dissipation limit	50 W
Maximum duty cycle	100%
Minimum duty cycle	0%

8.2.2 Detailed Design Procedure

Use VDD (5 V) as reference with gain 1 × to achieve an input range of (VDD/3) = 1.67 V, using Table 7-1. With a bus voltage of 48 V and ADC input range of 1.67 V, the external attenuation required is 28.74. Therefore, the attenuation resistors can be chosen as R_A = 100 kΩ and R_B = 3.6 kΩ. To limit the power dissipation to 50 W, the effective load resistance (R_{L-eff}) is calculated as (V_{BUS} ^{2}/P) = 46.08 Ω. That means a minimum duty-cycle of (R_L/ R_{L-eff}) = 10.85% is required. In a 7-bit scale, 10.85% corresponds to 13.89d. The required function coefficient, K can be calculated using Equation 4 to be 443.6d (0x01BC).

$$K = \frac{D_{MIN} \times (ADC - DATA_{MAX})^2}{2^{15}}$$

(4)

The PWM output pin is an open drain output. The PWM output pin must be pulled up to the desired IO voltage using an external resistor. The PWM frequency is set in the PWM-FREQUENCY SRAM location (SRAM: 0x23). Table 7-2 defines the codes for each available frequency. This example uses a PWM frequency of 3.052 kHz. Set the maximum and minimum PWM duty cycles limits in the MAX-OUTPUT and MIN-OUTPUT SRAM locations. The PWM duty cycle output is configured by a 7-bit code. The maximum code is 127d. 127d sets the PWM duty cycle to 100%. Table 7-3 provides more details about PWM duty cycle computation in AFE539F1-Q1.

Follow these guidelines to setup the registers on AFE539F1-Q1:
- Set the VREF/MODE pin low to enable the digital pins for programming mode.
- Stop the state machine before updating the application parameters by writing 0 to the STATE-MACHINE-CONFIG0 register.
- If the PWM generator is already running, stop the PWM generator before any changes to the PWM frequency take effect. Write a 0 to the START-FUNCTION field in the COMMON-PWM-TRIG register (0x21) to stop the PWM generator. The PWM generator automatically starts when the state machine is enabled.
- Set all of the application parameters shown in Table 8-2. Use these locations to save the settings in NVM.
- Configure the reference for the ADC in the REF-GAIN-CONFIG register.
- Power on the ADC channel using the COMMON-CONFIG register.
- Start the state machine by writing 0x3 to the STATE-MACHINE-CONFIG0.
- Trigger an NVM write by setting the NVM-PROG bit in the COMMON-TRIGGER register (0x20) to 1.
- Set the VREF/MODE pin high to enable the digital pins for standalone mode. This is required to see the PWM output on the digital pin.

Table 8-2. Application Parameters

REGISTER FIELD NAME	ADDRESS[FIELD]	ADDRESS LOCATION
MAX-OUTPUT	0x20[6:0]	SRAM
MIN-OUTPUT	0x21[6:0]	SRAM
FUNCTION-COEFFICIENT	0x22[15:0]	SRAM
PWM-FREQUENCY	0x23[4:0]	SRAM
REF-GAIN-CONFIG	0x15[12:10][4:0]	Register
COMMON-CONFIG	0x1F[15:0]	Register
STATE-MACHINE-CONFIG0	0x27[2:0]	Register

Product Folder Links: AFE539F1-Q1

The pseudocode for this application example is as follows:

```
//SYNTAX: WRITE <REGISTER NAME(Hex Code)>, <MSB DATA>, <LSB DATA>
//Stop the state machine
WRITE STATE-MACHINE-CONFIG0(0x27), 0x00, 0x01
//Stop the PWM generator
WRITE COMMON-PWM-TRIG(0x21), 0x00, 0x00
//Set the PWM frequncy to 3.052 kHz
WRITE PWM-FREQUENCY(SRAM 0x23), 0x00, 0x07
//Set the maximim and minimum PWM duty cycles
WRITE MAX-OUTPUT(SRAM 0x20), 0x00, 0x7F
WRITE MIN-OUTPUT(SRAM 0x21), 0x00, 0x00
//Set the function coefficient (K)
WRITE FUNCTION-COEFFICIENT(SRAM 0x22), 0x01, 0xBC
//Set the ADC reference to VDD (this is the device default)
WRITE REF-GAIN-CONFIG(0x15), 0x04, 0x01
//Power on ADC
WRITE COMMON-CONFIG(0x1F), 0x03, 0xFF
//Start the state machine
WRITE STATE-MACHINE-CONFIG0(0x27), 0x00, 0x03
//Save settings to NVM
WRITE COMMON-TRIGGER(0x20), 0x00, 0x02
//Pull the VREF/MODE pin high to enter standalone mode
```

8.2.3 Application Curve
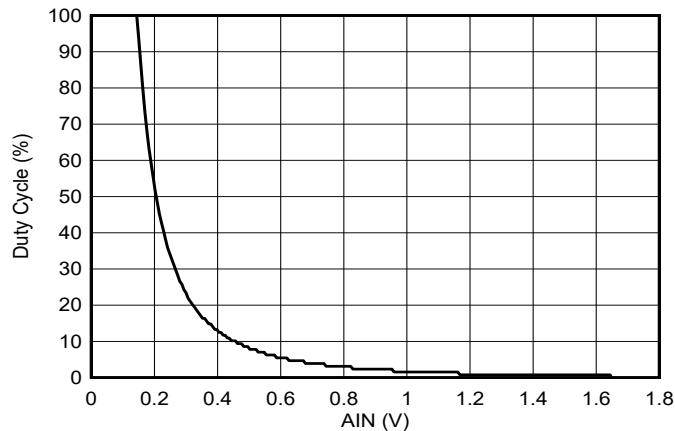
Figure 8-1. PWM Duty Cycle vs Input Voltage

Product Folder Links: *AFE539F1-Q1*

8.3 Power Supply Recommendations

The AFE539F1-Q1 do not require specific power-supply sequencing. These devices require a single power supply, V_{DD}. However, make sure the external voltage reference is applied after VDD powers on. Use a 0.1-µF decoupling capacitor for the V_{DD} pin. Use a bypass capacitor with a value approximately 1.5 µF for the CAP pin.

8.4 Layout

8.4.1 Layout Guidelines

The AFE539F1-Q1 pin configuration separates the analog, digital, and power pins for an optimized layout. For signal integrity, separate the digital and analog traces, and place decoupling capacitors close to the device pins.

8.4.2 Layout Example
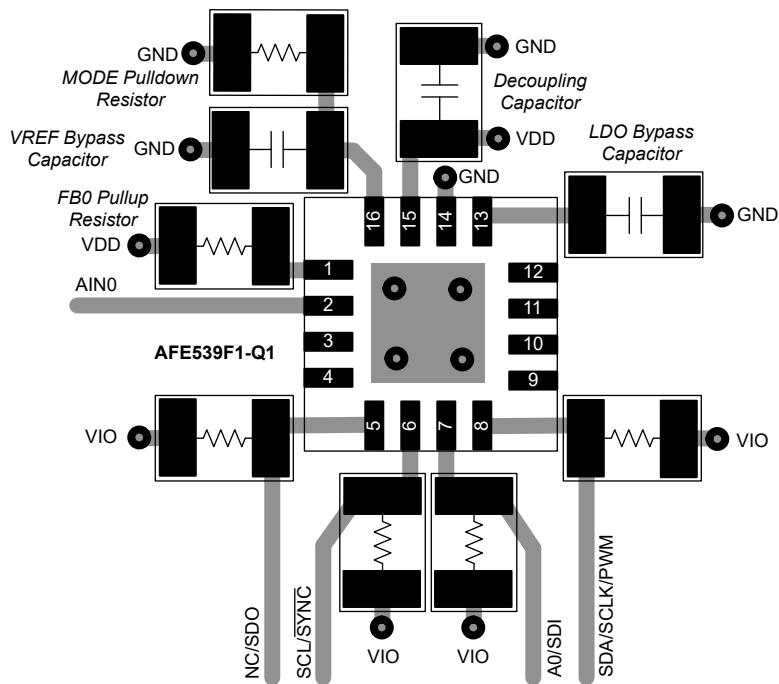
Figure 8-2. Layout Example

Note: The ground and power planes have been omitted for clarity. Connect the thermal pad to ground.

Product Folder Links: *AFE539F1-Q1*

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
AFE539F1RTERQ1	Active	Production	WQFN (RTE) | 16	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A59F1Q
AFE539F1RTERQ1.A	Active	Production	WQFN (RTE) | 16	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A59F1Q

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

Reel Diameter

Reel Width (W1)

TAPE DIMENSIONS

K0 P1

B0 W

Cavity A0
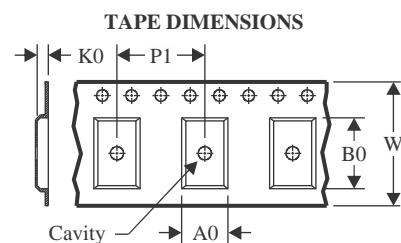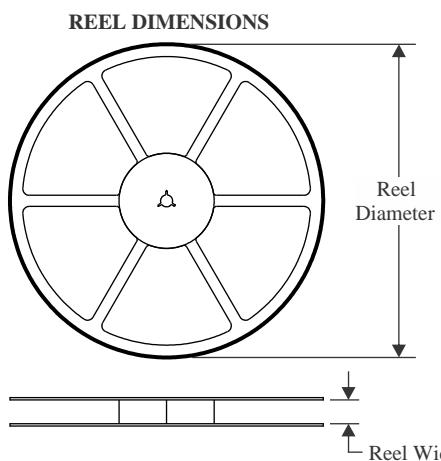
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Sprocket Holes

| Q1 | Q2 | | Q1 | Q2 |

| Q3 | Q4 | | Q3 | Q4 |

User Direction of Feed

Pocket Quadrants
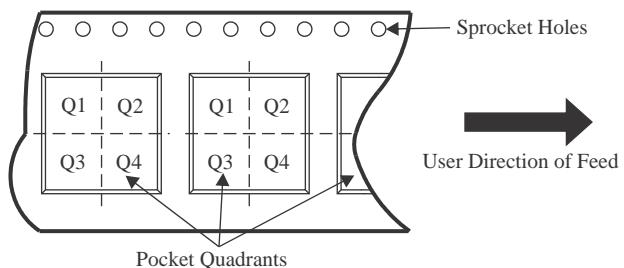
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
AFE539F1RTERQ1	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS
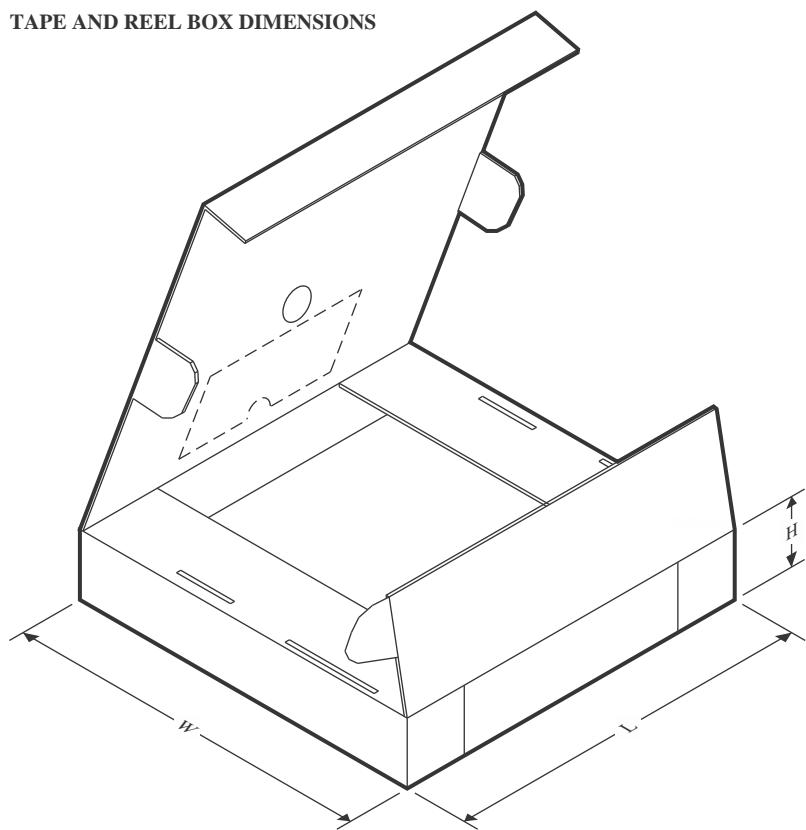
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
AFE539F1RTERQ1	WQFN	RTE	16	3000	367.0	367.0	35.0

RTE 16

WQFN - 0.8 mm max height

3 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4225944/A

PIN 1 INDEX AREA

3.1
2.9

3.1
2.9

A

B

SIDE WALL METAL THICKNESS DIM A	
OPTION 1	OPTION 2
0.1	0.2

0.8 MAX

0.05
0.00

C

SEATING PLANE

⌒ 0.08

☐ 1.68 ± 0.07

5

8

12X 0.5

4

4X

1.5

17

EXPOSED THERMAL PAD

9

SYMM ℄

1

PIN 1 ID
(OPTIONAL)

16

SYMM ℄

13

12

16X 0.30
0.18

⊕ 0.1 Ⓜ C A B
0.05 Ⓜ

16X 0.5
0.3

(DIM A) TYP

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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

(□ 1.68)

SYMM

16

13

16X (0.6)

1

16X (0.24)

12

17

SYMM

(2.8)

12X (0.5)

4

(0.58) TYP

9

(∅ 0.2) TYP
VIA

(R0.05)
ALL PAD CORNERS

5

8

(0.58) TYP

(2.8)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X

0.07 MAX
ALL AROUND

METAL

EXPOSED
METAL

SOLDER MASK
OPENING

NON SOLDER MASK
DEFINED
(PREFERRED)

0.07 MIN
ALL AROUND

SOLDER MASK
OPENING

EXPOSED
METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
DEFINED

SOLDER MASK DETAILS
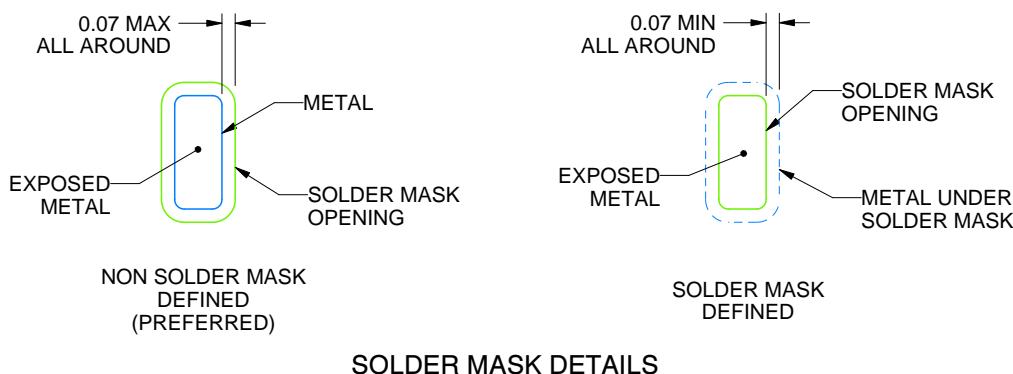
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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

(□ 1.55)

16

13

16X (0.6)

1

16X (0.24)

12

17

SYMM

(2.8)

12X (0.5)

4

9

METAL
ALL AROUND

5

8

SYMM

(R0.05) TYP

(2.8)

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 17:
85% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
design recommendations.

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